



ELECTRICAL – AND - THERMOELECTRIC LAWS, RELATIONS, AND COEFFICIENTS IN $n(p)$ - TYPE DEGENERATE COMPENSATED $\text{GaP}_{1-x}\text{Sb}_x$ (1-x) Sb (x) -CRYSTALLINE ALLOY, ENHANCED BY OUR STATIC DIELECTRIC CONSTANT LAW, ACCURATE FERMI ENERGY, AND ELECTRICAL CONDUCTIVITY MODEL (VIII)

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ABSTRACT

In the $n^+(p^+) - p(n) \text{X}(x) \equiv \text{GaP}_{1-x}\text{Sb}_x$ - crystalline alloy, $0 \leq x \leq 1$, the electrical-and-thermoelectric laws, relations, and various coefficients, enhanced by our static dielectric constant law given in Equations (1a, 1b), being due to the effects of the size of donor (acceptor) $d(a)$ -radius $r_{d(a)}$ and the x -concentration, by our accurate Fermi energy given in Eq. (11), and finally by our electrical conductivity-formula given in Eq. (14), are now investigated, basing on the same physical model and mathematical treatment method, as those used in our recent works (Van Cong, 2024, 2025). It should be noted here that, for $x=0$, these obtained numerical results may be reduced to those given in the $n(p)$ -type degenerate GaP-crystal. Then,

some remarkable results could be cited in the following. In Tables 5n(5p) given Appendix 1, for a given impurity density N and with increasing temperature T , and then in Tables 6n(6p) given Appendix 1, for a given T and with decreasing N , the reduced Fermi-energy $\xi_{n(p)}$ decreases, and other thermoelectric coefficients are in variations, as indicated by the arrows by: (increase: ↗, decrease: ↘). Further, one notes in these Tables that, for any given x , $r_{d(a)}$ and N (or T), with increasing T (or decreasing N) one obtains: (i) for $\xi_{n(p)} \simeq 1.8138$, while the numerical results of the Seebeck coefficient S present a same minimum

$(S)_{\min.} (\simeq -1.563 \times 10^{-4} \frac{V}{K})$, those of the figure of merit ZT show a same maximum $(ZT)_{\max.} = 1$, (ii) for $\xi_{n(p)} = 1$, the numerical results of S , ZT , the Mott figure of merit $(ZT)_{\text{Mott}}$, the first Van-Cong coefficient $VC1$, and the Thomson coefficient T_s , present the same results: $-1.322 \times 10^{-4} \frac{V}{K}$, 0.715 , 3.290 , $1.105 \times 10^{-4} \frac{V}{K}$, and $1.657 \times 10^{-4} \frac{V}{K}$, respectively, and finally (iii) for $\xi_n \simeq 1.8138$, $(ZT)_{\text{Mott}} = 1$. It seems that these same results could represent **a new law in the thermoelectric properties, obtained in the degenerate case.**

KEYWORDS: Electrical conductivity, Seebeck coefficient (S), Figure of merit (ZT), First Van-Cong coefficient ($VC1$), Second Van-Cong coefficient ($VC2$), Thomson coefficient (T_s), Peltier coefficient (Pt).

INTRODUCTION

In the $n^+(p^+) - p(n) X(x) \equiv GaP_{1-x}Sb_x$ - crystalline alloy, $0 \leq x \leq 1$, the electrical-and-thermoelectric laws, relations, and various coefficients, enhanced by our static dielectric constant law, $\varepsilon(r_{d(a)}, x)$, $r_{d(a)}$ being the donor (acceptor) $d(a)$ -radius, given in Equations (1a, 1b) and new electrical conductivity, in Eq. (14), and also by our accurate Fermi energy, $E_{Fn(Fp)}$, given in Eq. (11), are now investigated, by basing on the same physical model and mathematical treatment method, as those used in our recent works (Van Cong, 2024, 2025). It should be noted here that for $x=0$, these obtained numerical results may be reduced to those given in the $n(p)$ -type degenerate GaP-crystal (Van Cong, and Van Cong et al., 1980-2023; Hyun et al. 1998; Kim et al., 2015). Then, some remarkable results could be noted in the following.

(1) The generalized Mott criterium in the metal-insulator transition (**MIT**) is expressed in Equations (3, 5, 6), stating that the critical impurity density $N_{CDn(CDp)}$ is just the density of electrons (holes), localized in the exponential conduction (valence)-band tail (**EBT**), $N_{CDn(CDp)}^{EBT}$, obtained with a precision of the order of 2.92×10^{-7} , as given in our recent work (Van Cong, 2024), and the effective electron (hole)-density can be defined by: $N^* \equiv N - N_{CDn(CDp)} \simeq N - N_{CDn(CDp)}^{EBT}$, N being the total impurity density, as that observed in the compensated crystals.

(2) The ratio of the inverse effective screening length $k_{sn(sp)}$ to Fermi wave number $k_{Fn(kp)}$ at 0 K, $R_{sn(sp)}(N^*)$, defined in Eq. (7), is valid at any N^* .

(3) The Fermi energy for any N and T , $E_{Fn(Fp)}$, determined in Eq. (11) with a precision of the order of 2.11×10^{-4} (Van Cong and Debais, 1993), and it is present in all the expressions of electrical-and-thermoelectric coefficients.

(4) Our expressions for the electrical conductivity, σ , and for the Seebeck coefficient, S , determined respectively in Equations (14, 19) are the basic expressions, used to determine all the following electrical-and-thermoelectric coefficients.\

(5) In Tables 5n (5p) given Appendix 1, for a given impurity density N and with increasing temperature T , and sfurther in Tables 6n (6p) given Appendix 1, for a given T and with decreasing N , the reduced Fermi-energy $\xi_{n(p)}$ decreases, and other thermoelectric coefficients are in variations, as indicated by the arrows by: (increase: ↗, decrease: ↘). Furthermore, one notes in these Tables that, for any given x , $r_{d(a)}$ and N (or T), with increasing T (or decreasing N), one obtains: (i) for $\xi_{n(p)} \simeq 1.8138$, while the numerical results of the Seebeck coefficient S present a same minimum $(S)_{\min.} \left(\simeq -1.563 \times 10^{-4} \frac{V}{K} \right)$, those of the figure of merit ZT show a same maximum $(ZT)_{\max.} = 1$, (ii) for $\xi_{n(p)} = 1$, the numerical results of S , ZT , the Mott figure of merit $(ZT)_{\text{Mott}}$, the first Van-Cong coefficient $VC1$, and the Thomson coefficient Ts , present the same results: $-1.322 \times 10^{-4} \frac{V}{K}$, 0.715 , 3.290 , $1.105 \times 10^{-4} \frac{V}{K}$, and $1.657 \times 10^{-4} \frac{V}{K}$, respectively, and finally (iii) for $\xi_n \simeq 1.8138$, $(ZT)_{\text{Mott}} = 1$. It seems that these same results could represent a new law in the thermoelectric properties, obtained in the degenerate case.

Our static dielectric constant law and generalized mott criterium in the metal-insulator

transition: First of all, in the $n^+(p^+) - p(n)$ $X(x)$ - crystalline alloy at $T=0$ K, we denote the donor (acceptor) $d(a)$ -radius by $r_{d(a)}$, the corresponding intrinsic one by: $r_{do(ao)} = r_{Sb(Ga)}$, the unperturbed relative effective electron (hole) mass in conduction (valence) bands by: $m_{c(v)}(x)/m_o$, the unperturbed relative static dielectric constant by: $\epsilon_o(x)$, and the intrinsic band gap by: $E_{go}(x)$. Then, their values are reported in Table 1 in Appendix 1.

Therefore, we can define the effective donor (acceptor)-ionization energy in absolute values as: $E_{do(ao)}(x) = \frac{13600 \times [m_{c(v)}(x)/m_o]}{[\epsilon_o(x)]^2} \text{ meV}$, and then, the isothermal bulk modulus, by:

$$B_{do(ao)}(x) \equiv \frac{E_{do(ao)}(x)}{\left(\frac{4\pi}{3}\right) \times (r_{do(ao)})^3}.$$

Our Static Dielectric Constant Law: Here, the changes in all the energy-band-structure parameters, expressed in terms of the effective relative dielectric constant $\varepsilon(r_{d(a)}, x)$, developed as follows.

At $r_{d(a)} = r_{do(ao)}$, the needed boundary conditions are found to be, for the impurity-atom volume $V = (4\pi/3) \times (r_{d(a)})^3$, $V_{do(ao)} = (4\pi/3) \times (r_{do(ao)})^3$, for the pressure p , $p_o = 0$, and for the deformation potential energy (or the strain energy) α , $\alpha_o = 0$. Further, the two important equations, used to determine the α -variation, $\Delta\alpha \equiv \alpha - \alpha_o = \alpha$, are defined by:

$\frac{dp}{dV} = -\frac{B}{V}$ and $p = -\frac{d\alpha}{dV}$, giving rise to: $\frac{d}{dV}(\frac{d\alpha}{dV}) = \frac{B}{V}$. Then, by an integration, one gets:

$$[\Delta\alpha(r_{d(a)}, x)]_{n(p)} = B_{do(ao)}(x) \times (V - V_{do(ao)}) \times \ln\left(\frac{V}{V_{do(ao)}}\right) = E_{do(ao)}(x) \times \left[\left(\frac{r_{d(a)}}{r_{do(ao)}}\right)^3 - 1\right] \times \ln\left(\frac{r_{d(a)}}{r_{do(ao)}}\right)^3 \geq 0.$$

Furthermore, we also showed that, as $r_{d(a)} > r_{do(ao)}$ ($r_{d(a)} < r_{do(ao)}$), the compression (dilatation) gives rise to the increase (the decrease) in the energy gap $E_{gn(gp)}(r_{d(a)}, x)$, and the effective donor (acceptor)-ionization energy $E_{d(a)}(r_{d(a)}, x)$ in absolute values, obtained in the effective Bohr model, which is represented respectively by: $\pm [\Delta\alpha(r_{d(a)}, x)]_{n(p)}$,

$$E_{gno(gpo)}(r_{d(a)}, x) - E_{go}(x) = E_{d(a)}(r_{d(a)}, x) - E_{do(ao)}(x) = E_{do(ao)}(x) \times \left[\left(\frac{\varepsilon_o(x)}{\varepsilon(r_{d(a)})}\right)^2 - 1\right] = + [\Delta\alpha(r_{d(a)}, x)]_{n(p)}$$

for $r_{d(a)} \geq r_{do(ao)}$, and for $r_{d(a)} \leq r_{do(ao)}$,

$$E_{gno(gpo)}(r_{d(a)}, x) - E_{go}(x) = E_{d(a)}(r_{d(a)}, x) - E_{do(ao)}(x) = E_{do(ao)}(x) \times \left[\left(\frac{\varepsilon_o(x)}{\varepsilon(r_{d(a)})}\right)^2 - 1\right] = - [\Delta\alpha(r_{d(a)}, x)]_{n(p)}$$

Therefore, one obtains the expressions for relative dielectric constant $\varepsilon(r_{d(a)}, x)$ and energy band gap $E_{gn(gp)}(r_{d(a)}, x)$, as:

$$(i)\text{-for } r_{d(a)} \geq r_{do(ao)}, \quad \text{since } \varepsilon(r_{d(a)}, x) = \frac{\varepsilon_o(x)}{\sqrt{1 + \left[\left(\frac{r_{d(a)}}{r_{do(ao)}}\right)^3 - 1\right] \times \ln\left(\frac{r_{d(a)}}{r_{do(ao)}}\right)^3}} \leq \varepsilon_o(x), \text{ being a new}$$

$\varepsilon(r_{d(a)}, x)$ -law,

$$E_{gno(gpo)}(r_{d(a)}, x) - E_{go}(x) = E_{d(a)}(r_{d(a)}, x) - E_{do(ao)}(x) = E_{do(ao)}(x) \times \left[\left(\frac{r_{d(a)}}{r_{do(ao)}}\right)^3 - 1\right] \times \ln\left(\frac{r_{d(a)}}{r_{do(ao)}}\right)^3 \geq 0, \quad (1a)$$

according to the increase in both $E_{\text{gn(gp)}}(r_{\text{d(a)}}, x)$ and $E_{\text{d(a)}}(r_{\text{d(a)}}, x)$, with increasing $r_{\text{d(a)}}$ and for a given x , and (ii)-for $r_{\text{d(a)}} \leq r_{\text{do(ao)}}$, since $\varepsilon(r_{\text{d(a)}}, x) = \frac{\varepsilon_0(x)}{\sqrt{1 - \left[\left(\frac{r_{\text{d(a)}}}{r_{\text{do(ao)}}}\right)^3 - 1\right] \times \ln\left(\frac{r_{\text{d(a)}}}{r_{\text{do(ao)}}}\right)^3}} \geq \varepsilon_0(x)$, with a

condition, given by: $\left[\left(\frac{r_{\text{d(a)}}}{r_{\text{do(ao)}}}\right)^3 - 1\right] \times \ln\left(\frac{r_{\text{d(a)}}}{r_{\text{do(ao)}}}\right)^3 < 1$, being a **new $\varepsilon(r_{\text{d(a)}}, x)$ -law**,

$$E_{\text{gno(gp)}}(r_{\text{d(a)}}, x) - E_{\text{go}}(x) = E_{\text{d(a)}}(r_{\text{d(a)}}, x) - E_{\text{do(ao)}}(x) = -E_{\text{do(ao)}}(x) \times \left[\left(\frac{r_{\text{d(a)}}}{r_{\text{do(ao)}}}\right)^3 - 1\right] \times \ln\left(\frac{r_{\text{d(a)}}}{r_{\text{do(ao)}}}\right)^3 \leq 0, \quad (1b)$$

corresponding to the decrease in both $E_{\text{gno(gp)}}(r_{\text{d(a)}}, x)$ and $E_{\text{d(a)}}(r_{\text{d(a)}}, x)$, with decreasing $r_{\text{d(a)}}$ and for a given x . It should be noted that, in the following, all the electrical-and-thermoelectric properties strongly depend on this **new $\varepsilon(r_{\text{d(a)}}, x)$ -law**. Furthermore, the effective Bohr radius $a_{\text{Bn(Bp)}}(r_{\text{d(a)}}, x)$ is defined by:

$$a_{\text{Bn(Bp)}}(r_{\text{d(a)}}, x) \equiv \frac{\varepsilon(r_{\text{d(a)}}, x) \times \hbar^2}{m_{\text{c(v)}}(x) \times m_0 \times q^2} = 0.53 \times 10^{-8} \text{ cm} \times \frac{\varepsilon(r_{\text{d(a)}}, x)}{m_{\text{c(v)}}(x)}. \quad (2)$$

Generalized Mott Criterium in the MIT: Now, it is interesting to remark that the critical total donor (acceptor)-density in the MIT at $T=0$ K, $N_{\text{CDn(NDp)}}(r_{\text{d(a)}}, x)$, was given by the Mott's criterium, with an empirical parameter, $M_{\text{n(p)}}$, as:

$$N_{\text{CDn(CDp)}}(r_{\text{d(a)}}, x)^{1/3} \times a_{\text{Bn(Bp)}}(r_{\text{d(a)}}, x) = M_{\text{n(p)}}, \quad M_{\text{n(p)}} = 0.25, \quad (3)$$

depending thus on our **new $\varepsilon(r_{\text{d(a)}}, x)$ -law**.

This excellent one can be explained from the definition of the reduced effective Wigner-Seitz (WS) radius $r_{\text{sn(sp)}}$, characteristic of interactions, by:

$$r_{\text{sn(sp)}}(N, r_{\text{d(a)}}, x) \equiv \left(\frac{3}{4\pi N}\right)^{1/3} \times \frac{1}{a_{\text{Bn(Bp)}}(r_{\text{d(a)}}, x)} = 1.1723 \times 10^8 \times \left(\frac{1}{N}\right)^{1/3} \times \frac{m_{\text{c(v)}}(x) \times m_0}{\varepsilon(r_{\text{d(a)}}, x)}, \quad (4)$$

being equal to, in particular, at $N=N_{\text{CDn(CDp)}}(r_{\text{d(a)}}, x)$: $r_{\text{sn(sp)}}(N_{\text{CDn(CDp)}}(r_{\text{d(a)}}, x), r_{\text{d(a)}}, x) = 2.4813963$, for any $(r_{\text{d(a)}}, x)$ -values. Then, from Eq. (4), one also has:

$$N_{\text{CDn(CDp)}}(r_{\text{d(a)}}, x)^{1/3} \times a_{\text{Bn(Bp)}}(r_{\text{d(a)}}, x) = \left(\frac{3}{4\pi}\right)^{1/3} \times \frac{1}{2.4813963} = 0.25 = (\text{WS})_{\text{n(p)}} = M_{\text{n(p)}}, \quad (5)$$

Explaining thus the existence of the Mott's criterium

Furthermore, by using $M_{\text{n(p)}} = 0.25$, according to the empirical Heisenberg parameter $\mathcal{H}_{\text{n(p)}} = 0.47137$, as those given in our previous work (Van Cong, 2024), we have also showed that $N_{\text{CDn(CDp)}}$ is just **the density of electrons (holes) localized in the exponential conduction (valence)-band tail**, $N_{\text{CDn(CDp)}}^{\text{EBT}}$, with a precision of the order of 2.92×10^{-7} .

It should be noted that the values of $M_{n(p)}$ and $\mathcal{H}_{n(p)}$ could be chosen so that those of $N_{CDn(CDp)}$ and $N_{CDn(CDp)}^{EBT}$ are found to be in good agreement with their experimental results.

Therefore, the density of electrons (holes) given in parabolic conduction (valence) bands can be defined, as that given in compensated materials:

$$N^*(N, r_{d(a)}, x) \equiv N - N_{CDn(NDp)}(r_{d(a)}, x) = N^*, \text{ for a presentation simplicity.} \quad (6)$$

In summary, as observed in Table 4 of our previous paper (Van Cong, 2024), one remarks that, for a given x and an increasing $r_{d(a)}$, $\varepsilon(r_{d(a)}, x)$ decreases, while $E_{gno(gpo)}(r_{d(a)}, x)$, $N_{CDn(NDp)}(r_{d(a)}, x)$ and $N_{CDn(CDp)}^{EBT}(r_{d(a)}, x)$ increase, affecting strongly all electrical-and-thermoelectric properties, as those observed in following Sections.

PHYSICAL MODEL

In the $n^+(p^+) - p(n) X(x)$ - crystalline alloy, if denoting the Fermi wave number by:

$k_{Fn(Fp)}(N^*) \equiv \left(\frac{3\pi^2 N^*}{g_c(v)} \right)^{\frac{1}{3}}$, the reduced effective Wigner-Seitz (WS) radius $r_{sn(sp)}$, characteristic of interactions, being given in Eq. (4), in which N is replaced by N^* , is now defined by:

$$\gamma \times r_{sn(sp)}(N^*) \equiv \frac{k_{Fn(Fp)}^{-1}}{a_{Bn(Bp)}} < 1,$$

being proportional to $N^{*-1/3}$. Here, $\gamma = (4/9\pi)^{1/3}$, $k_{Fn(Fp)}^{-1}$ means the averaged distance between ionized donors (acceptors), and $a_{Bn(Bp)}(r_{d(a)}, x)$ is determined in Eq. (2).

Then, the ratio of the inverse effective screening length $k_{sn(sp)}$ to Fermi wave number $k_{Fn(kp)}$ at 0 K is defined by:

$$R_{sn(sp)}(N^*) \equiv \frac{k_{sn(sp)}}{k_{Fn(Fp)}} = \frac{k_{Fn(Fp)}^{-1}}{k_{sn(sp)}^{-1}} = R_{snWS(spWS)} + [R_{snTF(spTF)} - R_{snWS(spWS)}]e^{-r_{sn(sp)}} < 1, \quad (7)$$

Being valid at any N^* .

Here, these ratios, $R_{snTF(spTF)}$ and $R_{snWS(spWS)}$, can be determined as follows. First, for $N \gg N_{CDn(NDp)}(r_{d(a)}, x)$, according to the **Thomas-Fermi (TF)-approximation**, the ratio

$$R_{snTF(spTF)}(N^*) \text{ is reduced to } R_{snTF(spTF)}(N^*) \equiv \frac{k_{snTF(spTF)}}{k_{Fn(Fp)}} = \frac{k_{Fn(Fp)}^{-1}}{k_{snTF(spTF)}^{-1}} = \sqrt{\frac{4\gamma r_{sn(sp)}}{\pi}} \ll 1, \quad (8)$$

being proportional to $N^{*-1/6}$.

Secondly, for $N \ll N_{CDn(NDp)}(r_{d(a)})$, according to the **Wigner-Seitz (WS)-approximation**, the ratio $R_{snWS(snWS)}$ is respectively reduced to

$$R_{sn(sp)WS}(N^*) \equiv \frac{k_{sn(sp)WS}}{k_{Fn}} = 0.5 \times \left(\frac{3}{2\pi} - \gamma \frac{d[r_{sn(sp)}^2 \times E_{CE}(N^*)]}{dr_{sn(sp)}} \right), \quad (9)$$

where $E_{CE}(N^*)$ is the majority-carrier correlation energy (CE), being determined by:

$$E_{CE}(N^*) = \frac{-0.87553}{0.0908 + r_{sn(sp)}} + \frac{\frac{0.87553}{0.0908 + r_{sn(sp)}} + \left(\frac{2[1 - \ln(2)]}{\pi^2} \right) \times \ln(r_{sn(sp)}) - 0.093288}{1 + 0.03847728 \times r_{sn(sp)}^{1.67378876}}.$$

Furthermore, in the highly degenerate case, the physical conditions are found to be given by:

$$\frac{k_{Fn(Fp)}^{-1}}{a_{Bn(Bp)}} < \frac{\eta_{n(p)}}{E_{Fn(Fp)}} \equiv \frac{1}{A_{n(p)}} < \frac{k_{Fn(Fp)}^{-1}}{k_{sn(sp)}^{-1}} \equiv R_{sn(sp)} < 1, \quad \eta_{n(p)}(N^*) \equiv \frac{\sqrt{2\pi N^*}}{z(r_{d(a)})} \times q^2 k_{sn(sp)}^{-1/2}, \quad (10)$$

$$\text{which gives: } A_{n(p)}(N^*) = \frac{E_{Fn(Fp)}(N^*)}{\eta_{n(p)}(N^*)}.$$

FERMI ENERGY AND FERMI-DIRAC DISTRIBUTION FUNCTION

Fermi Energy

Here, for a presentation simplicity, we change all the sign of various parameters, given in the $p^+ - X(x)$ - crystalline alloy in order to obtain the same one, as given in the $n^+ - X(x)$ - crystalline alloy, according to the reduced Fermi energy $E_{Fn(Fp)}, \xi_{n(p)}(N, r_{d(a)}, x, T) \equiv \frac{E_{Fn(Fp)}(N, r_{d(a)}, x, T)}{k_B T} > 0 (< 0)$, obtained respectively in the degenerate (non-degenerate) case.

For any $(N, r_{d(a)}, x, T)$, the reduced Fermi energy $\xi_{n(p)}(N, r_{d(a)}, x, T)$ or the Fermi energy $E_{Fn(Fp)}(N, r_{d(a)}, x, T)$, obtained in our previous paper (Van Cong, Debiais, and Doan Khanh, 1991- 1993), obtained with a precision of the order of 2.11×10^{-4} , is found to be given by:

$$\xi_{n(p)}(u) \equiv \frac{E_{Fn(Fp)}(u)}{k_B T} = \frac{G(u) + Au^B F(u)}{1 + Au^B} \equiv \frac{V(u)}{W(u)}, \quad A = 0.0005372 \text{ and } B = 4.82842262, \quad (11)$$

Where u is the reduced electron density, $u(N, r_{d(a)}, x, T) \equiv \frac{N^*}{N_{c(v)}(T, x)}$,

$$N_{c(v)}(T, x) = 2g_{c(v)} \times \left(\frac{m_{c(v)}(x) \times m_0 \times k_B T}{2\pi\hbar^2} \right)^{\frac{3}{2}} (\text{cm}^{-3}), \quad g_{c(v)} = 1, \quad F(u) = au^{\frac{2}{3}} \left(1 + bu^{-\frac{4}{3}} + cu^{-\frac{8}{3}} \right)^{-\frac{2}{3}},$$

$$a = [3\sqrt{\pi}/4]^{2/3}, \quad b = \frac{1}{8} \left(\frac{\pi}{a} \right)^2, \quad c = \frac{62.3739855}{1920} \left(\frac{\pi}{a} \right)^4, \quad \text{and} \quad G(u) \simeq \ln(u) + 2^{-\frac{3}{2}} \times u \times e^{-du};$$

$$d = 2^{3/2} \left[\frac{1}{\sqrt{27}} - \frac{3}{16} \right] > 0.$$

So, in the non-degenerate case ($u \ll 1$), one has: $E_{Fn(Fp)}(u) = k_B T \times G(u) \simeq k_B T \times \ln(u)$ as $u \rightarrow 0$, the limiting non-degenerate condition, and in the very degenerate case ($u \gg 1$), one

gets: $E_{Fn(Fp)}(u \gg 1) = k_B T \times F(u) = k_B T \times au^{\frac{2}{3}} \left(1 + bu^{-\frac{4}{3}} + cu^{-\frac{8}{3}}\right)^{-\frac{2}{3}} \simeq \frac{\hbar^2 \times k_{Fn(Fp)}^2 (N^*)}{2 \times m_{c(v)}(x) \times m_0}$ as

$u \rightarrow \infty$, the limiting degenerate condition. In other words, $\xi_{n(p)} \equiv \frac{E_{Fn(Fp)}}{k_B T}$ is accurate, and it also verifies the correct limiting conditions.

In particular, at $T=0K$, since $u^{-1} = 0$, Eq. (11) is reduced to: $E_{Fno(Fpo)}(N^*) \equiv \frac{\hbar^2 \times k_{Fn(Fp)}^2 (N^*)}{2 \times m_{c(v)}(x) \times m_0}$,

being proportional to $(N^*)^{2/3}$, and also equal to 0 at $N^* = 0$, according to the MIT.

In the following, it should be noted that all the electrical-and-thermoelectric properties strongly depend on such the accurate expression of $\xi_{n(p)}(N, r_{d(a)}, x, T)$.

Fermi-Dirac Distribution Function (FDDF)

The Fermi-Dirac distribution function (FDDF) is given by: $f(E) \equiv (1 + e^\gamma)^{-1}$, $\gamma \equiv (E - E_{Fn(Fp)})/(k_B T)$.

So, the average of E^p , calculated using the FDDF-method, as developed in our previous work (Van Cong, 2018, 2025) is found to be given by:

$$\langle E^p \rangle_{FDDF} \equiv G_p(E_{Fn(Fp)}) \times E_{Fn(Fp)}^p \equiv \int_{-\infty}^{\infty} E^p \times \left(-\frac{\partial f}{\partial E}\right) dE, \quad -\frac{\partial f}{\partial E} = \frac{1}{k_B T} \times \frac{e^\gamma}{(1+e^\gamma)^2}.$$

Further, one notes that, at 0 K, $-\frac{\partial f}{\partial E} = \delta(E - E_{Fno(Fpo)})$, $\delta(E - E_{Fno(Fpo)})$ being the Dirac delta (δ)-function. Therefore, $G_p(E_{Fno(Fpo)}) = 1$.

Then, at low T, by a variable change $\gamma \equiv (E - E_{Fn(Fp)})/(k_B T)$, one has:

$$G_p(E_{Fn(Fp)}) \equiv 1 + E_{Fn(Fp)}^{-p} \times \int_{-\infty}^{\infty} \frac{e^\gamma}{(1+e^\gamma)^2} \times (k_B T \gamma + E_{Fn(Fp)})^p d\gamma = 1 + \sum_{\mu=1,2,\dots}^p C_p^\beta \times (k_B T)^\beta \times E_{Fn(Fp)}^{-\beta} \times I_\beta,$$

where $C_p^\beta \equiv p(p-1) \dots (p-\beta+1)/\beta!$ and the integral I_β is given by:

$$I_\beta = \int_{-\infty}^{\infty} \frac{\gamma^\beta \times e^\gamma}{(1+e^\gamma)^2} d\gamma = \int_{-\infty}^{\infty} \frac{\gamma^\beta}{(e^{\gamma/2} + e^{-\gamma/2})^2} d\gamma, \text{ vanishing for odd values of } \beta. \text{ Then, for even values}$$

of $\beta = 2n$, with $n=1, 2, \dots$, one obtains: $I_{2n} = 2 \int_0^{\infty} \frac{\gamma^{2n} \times e^\gamma}{(1+e^\gamma)^2} d\gamma$.

Now, using an identity $(1 + e^\gamma)^{-2} \equiv \sum_{s=1}^{\infty} (-1)^{s+1} s \times e^{\gamma(s-1)}$, a variable change: $s\gamma = -t$, the Gamma function: $\int_0^{\infty} t^{2n} e^{-t} dt \equiv \Gamma(2n+1) = (2n)!$, and also the definition of the Riemann's zeta function: $\zeta(2n) \equiv 2^{2n-1} \pi^{2n} |B_{2n}|/(2n)!$, B_{2n} being the Bernoulli numbers, one finally gets: $I_{2n} = (2^{2n} - 2) \times \pi^{2n} \times |B_{2n}|$. So, from above Eq. of $\langle E^p \rangle_{FDDF}$, we get in the degenerate case the following ratio:

$$G_p(E_{Fn(Fp)}) \equiv \frac{\langle E^p \rangle_{FDDF}}{E_{Fn(Fp)}^p} = 1 + \sum_{n=1}^p \frac{p(p-1) \dots (p-2n+1)}{(2n)!} \times (2^{2n} - 2) \times |B_{2n}| \times \gamma^{2n} \equiv G_{p \geq 1}(\gamma), \quad (12)$$

$$\text{where } y \equiv \frac{\pi}{\xi_{n(p)}(N^*, T)} = \frac{\pi k_B T}{E_{Fn(Fp)}(N^*, T)}.$$

Then, some usual results of $G_{p \geq 1}(y)$ are given in Table 2 in Appendix 1, being needed to determine all the following electrical-and-thermoelectric properties.

ELECTRICAL-AND-THERMOELECTRIC PROPERTIES: Here, if denoting, for majority electrons (holes), the electrical conductivity by $\sigma(N, r_{d(a)}, x, T)$ expressed in $\text{ohm}^{-1} \times \text{cm}^{-1}$, the thermal conductivity by $\kappa(N, r_{d(a)}, x, T)$ in $\frac{W}{\text{cm} \times K}$, and the Lorenz number L defined by: $L = \frac{\pi^2}{3} \times \left(\frac{k_B}{q}\right)^2 = 2.4429637 \left(\frac{W \times \text{ohm}}{K^2}\right) = 2.4429637 \times 10^{-8} (V^2 \times K^{-2})$, then the well-known Wiedemann-Frank law states that the ratio, $\frac{\kappa}{\sigma}$, is proportional to the temperature $T(K)$, as: $\frac{\kappa(N, r_{d(a)}, x, T)}{\sigma(N, r_{d(a)}, x, T)} = L \times T$. (13)

We now determine the general form of σ in the following.

First of all, it is expressed in terms of the kinetic energy of the electron (hole),

$$E_k \equiv \frac{\hbar^2 \times k^2}{2 \times m_{cn(cp)} \times m_0}, \text{ or the wave number } k, \text{ as: } \sigma(k) \equiv \frac{q^2 \times k}{\pi \times \hbar} \times \frac{k}{k_{sn(sp)}} \times [k \times a_{Bn(Bp)}] \times \left(\frac{E_k}{\eta_{n(p)}}\right)^{1/2},$$

which is thus proportional to E_k^2 .

Then, for $E \geq 0$, we obtain:

$$\langle E^2 \rangle_{FDDF} \equiv G_2(y = \frac{\pi k_B T}{E_{Fn(Fp)}}) \times E_{Fn(Fp)}^2, \text{ and } G_2(y) = \left(1 + \frac{y^2}{3}\right) \equiv G_2(N, r_{d(a)}, x, T),$$

with $y \equiv \frac{\pi}{\xi_{n(p)}}$, $\xi_{n(p)} = \xi_{n(p)}(N, r_{d(a)}, x, T)$ for a presentation simplicity. Therefore, one obtains (Van Cong, 2025):

$$\sigma(N, r_{d(a)}, x, T) \equiv \left[\frac{q^2}{\pi \times \hbar} \times \frac{k_{Fn(Fp)}(N^*)}{R_{sn(sp)}(N^*)} \times [k_{Fn(Fp)}(N^*) \times a_{Bn(Bp)}(r_{d(a)})] \times \sqrt{A_{n(p)}(N^*)} \right] \times \left[G_2(N, r_{d(a)}, x, T) \times \left(\frac{E_{Fn(Fp)}(N, r_{d(a)}, x, T)}{E_{Fno(Fpo)}(N^*)} \right)^2 \right] \left(\frac{1}{\text{ohm} \times \text{cm}} \right),$$

$$\frac{q^2}{\pi \times \hbar} = 7.7480735 \times 10^{-5} \text{ ohm}^{-1}, A_{n(p)}(N^*) = \frac{E_{Fno(Fpo)}(N^*)}{\eta_{n(p)}(N^*)}, R_{sn(sp)}(N^*) \equiv \frac{k_{sn(sp)}}{k_{Fn(Fp)}}, \quad (14)$$

which can be used to define the resistivity as: $\rho(N, r_{d(a)}, x, T) \equiv 1/\sigma(N, r_{d(a)}, x, T)$, noting again that $N^* \equiv N - N_{CDn(NDp)}(r_{d(a)}, x)$. This $\sigma(N, r_{d(a)}, x, T)$ -result is an essential one in this paper, being used to determine other electrical-and-thermoelectric properties.

In Eq. (14), one notes that at $T = 0 \text{ K}$, $\sigma(N, r_{d(a)}, x, T = 0 \text{ K})$ is proportional to $E_{Fno(Fpo)}^2$, or to $(N^*)^{\frac{4}{3}}$. Thus, $\sigma(N = N_{CDn(NDp)}, r_{d(a)}, x, T = 0 \text{ K}) = 0$ at $N^* = 0$, at which the metal-insulator transition (MIT) occurs.

Electrical Coefficients

The relaxation time τ is related to σ by (Van Cong, 2025):

$$\tau(N, r_{d(a)}, x, T) \equiv \sigma(N, r_{d(a)}, x, T) \times \frac{m_{c(v)}(x) \times m_0}{q^2 \times N^*}. \text{ Therefore, the mobility } \mu \text{ is given by:}$$

$$\mu(N, r_{d(a)}, x, T) \equiv \mu(N^*, r_{d(a)}, T) = \frac{q \times \tau(N, r_{d(a)}, x, T)}{m_{c(v)}(x) \times m_0} = \frac{\sigma(N, r_{d(a)}, x, T)}{q \times N^*} \left(\frac{\text{cm}^2}{V \times s} \right). \quad (15)$$

Here, at $T = 0K$, $\mu(N^*, r_{d(a)}, T)$ is thus proportional to $(N^*)^{1/3}$, since $\sigma(N^*, r_{d(a)}, T = 0K)$ is proportional to $(N^*)^{4/3}$. Thus, $\mu(N^* = 0, r_{d(a)}, T = 0K) = 0$ at $N^* = 0$, at which the metal-insulator transition (MIT) occurs.

Then, since τ and σ are both proportional to $E_{Fn(Fp)}(N^*, T)^2$, as given above, the Hall factor is defined by:

$$r_H(N, r_{d(a)}, x, T) \equiv \frac{\langle \tau^2 \rangle_{FDDF}}{[\langle \tau \rangle_{FDDF}]^2} = \frac{G_4(y)}{[G_2(y)]^2}, \quad y \equiv \frac{\pi}{\xi_{n(p)}(N, r_{d(a)}, x, T)} = \frac{\pi k_B T}{E_{Fn(Fp)}(N, r_{d(a)}, x, T)}, \text{ and therefore, the Hall mobility yields:}$$

$$\mu_H(N, r_{d(a)}, x, T) \equiv \mu(N, r_{d(a)}, x, T) \times r_H(N^*, T) \left(\frac{\text{cm}^2}{V \times s} \right), \quad (16)$$

noting that, at $T=0K$, since $r_H(N, r_{d(a)}, x, T) = 1$, one then gets: $\mu_H(N, r_{d(a)}, x, T) \equiv \mu(N, r_{d(a)}, x, T)$.

Our generalized Einstein relation

Our generalized Einstein relation is found to be defined as:

$$S \frac{D(N, r_{d(a)}, x, T)}{\mu(N, r_{d(a)}, x, T)} \equiv \frac{N^*}{q} \times \frac{dE_{Fn(Fp)}}{dN^*} \equiv \frac{k_B \times T}{q} \times \left(u \frac{d\xi_{n(p)}(u)}{du} \right) = \sqrt{\frac{3 \times L}{\pi^2}} \times T \times \left(u \frac{d\xi_{n(p)}(u)}{du} \right), \quad \frac{k_B}{q} = \sqrt{\frac{3 \times L}{\pi^2}} \quad (17)$$

where $D(N, r_{d(a)}, x, T)$ is the diffusion coefficient, $\xi_{n(p)}(u)$ is defined in Eq. (11), and the mobility $\mu(N, r_{d(a)}, x, T)$ is determined in Eq. (15). Then, by differentiating this function $\xi_{n(p)}(u)$ with respect to u , one thus obtains $\frac{d\xi_{n(p)}(u)}{du}$. Therefore, Eq. (17) can also be rewritten

$$\text{as: } \frac{D(N, r_{d(a)}, x, T)}{\mu(N, r_{d(a)}, x, T)} = \frac{k_B \times T}{q} \times u \frac{V'(u) \times W(u) - V(u) \times W'(u)}{W^2(u)},$$

where $W'(u) = ABu^{B-1}$ and

$$V'(u) = u^{-1} + 2^{-\frac{3}{2}} e^{-du} (1 - du) + \frac{2}{3} Au^{B-1} F(u) \left[\left(1 + \frac{3B}{2} \right) + \frac{4}{3} \times \frac{bu^{-\frac{4}{3} + 2cu - \frac{8}{3}}}{1 + bu^{-\frac{4}{3} + cu - \frac{8}{3}}} \right].$$

One remarks that: (i) as $u \rightarrow 0$, one has: $W^2 \simeq 1$ and $u[V' \times W - V \times W'] \simeq 1$, and therefore:

$$\frac{D_{n(p)}(u)}{\mu} \simeq \frac{k_B \times T}{q}, \quad \text{and} \quad (ii) \quad \text{as} \quad u \rightarrow \infty, \quad \text{one} \quad \text{has: } W^2 \approx A^2 u^{2B} \quad \text{and}$$

$$u[V' \times W - V \times W'] \approx \frac{2}{3} au^{2/3} A^2 u^{2B}, \text{ and therefore, in this highly degenerate case and at}$$

$T=0K$, the **above generalized Einstein relation** is reduced to the **usual Einstein one**:

$\frac{D(N, r_{d(a)}, x, T=0 \text{ K})}{\mu(N, r_{d(a)}, x, T=0 \text{ K})} \approx \frac{2}{3} E_{\text{Fno}}(F_{\text{po}})(N^*)/q$. In other words, Eq. (17) verifies the correct limiting conditions.

Furthermore, in the present degenerate case ($u \gg 1$), Eq. (17) gives:

$$\frac{D(N, r_{d(a)}, x, T)}{\mu(N, r_{d(a)}, x, T)} \simeq \frac{2}{3} \times \frac{E_{\text{Fno}}(F_{\text{po}})(u)}{q} \times \left[1 + \frac{4}{3} \times \frac{\left(bu^{-\frac{4}{3}} + 2cu^{-\frac{8}{3}} \right)}{\left(1 + bu^{-\frac{4}{3}} + cu^{-\frac{8}{3}} \right)} \right], \quad (18)$$

where $a = [3\sqrt{\pi}/4]^{2/3}$, $b = \frac{1}{8} \left(\frac{\pi}{a} \right)^2$ and $c = \frac{62.3739855}{1920} \left(\frac{\pi}{a} \right)^4$.

In Tables 3n (3p) given in Appendix 1, for given x , $N > N_{\text{CDn}}$ and $T (= 4.2 \text{ K and } 77 \text{ K})$, and from Equations (14, 15, 16, 17), the numerical results of the coefficients: σ, μ, μ_H and D are found to be decreased with increasing $r_{d(a)}$, respectively.

Thermoelectric Coefficients

First of all, from Eq. (14), obtained for $\sigma(N, r_{d(a)}, x, T)$, the well-known Mott definition for the thermoelectric power or for the Seebeck coefficient, S , is found to be given by:

$$S(N, r_{d(a)}, x, T) \equiv \frac{-\pi^2}{3} \times \frac{k_B}{q} \times k_B T \times \left. \frac{\partial \ln \sigma(E)}{\partial E} \right|_{E=E_{\text{Fn}}(F_p)} = \frac{-\pi^2}{3} \times \frac{k_B}{q} \times \frac{\partial \ln \sigma(\xi_{n(p)})}{\partial \xi_{n(p)}}.$$

Then, using Eq. (11), for the degenerate case, $\xi_{n(p)} \geq 0$, one gets, by putting

$$F_S(N, r_{d(a)}, x, T) \equiv \left[1 - \frac{y^2}{3 \times G_2 \left(y = \frac{\pi}{\xi_{n(p)}} \right)} \right],$$

$$S(N, r_{d(a)}, x, T) \equiv \frac{-\pi^2}{3} \times \frac{k_B}{q} \times \frac{2F_{\text{Sb}}(N^*, T)}{\xi_{n(p)}} = -\sqrt{\frac{3 \times L}{\pi^2}} \times \frac{2 \times \xi_{n(p)}}{\left(1 + \frac{3 \times \xi_{n(p)}^2}{\pi^2} \right)} = -2\sqrt{L} \times \frac{\sqrt{(ZT)_{\text{Mott}}}}{1 + (ZT)_{\text{Mott}}} \left(\frac{V}{K} \right) <$$

$$0, \quad (ZT)_{\text{Mott}} = \frac{\pi^2}{3 \times \xi_{n(p)}^2} \quad , \quad (19)$$

$$\text{according to: } s \frac{\partial S}{\partial \xi_{n(p)}} = \sqrt{\frac{3 \times L}{\pi^2}} \times 2 \times \frac{\frac{3 \times \xi_{n(p)}^2}{\pi^2} - 1}{\left(1 + \frac{3 \times \xi_{n(p)}^2}{\pi^2} \right)^2} = \sqrt{\frac{3 \times L}{\pi^2}} \times 2 \times \frac{(ZT)_{\text{Mott}} \times [1 - (ZT)_{\text{Mott}}]}{[1 + (ZT)_{\text{Mott}}]^2}.$$

Here, one notes that: (i) as $\xi_{n(p)} \rightarrow +\infty$ or $\xi_{n(p)} \rightarrow +0$, one has a same limiting value of S :

$S \rightarrow -0$, (ii) at $\xi_{n(p)} = \sqrt{\frac{\pi^2}{3}} \simeq 1.8138$, since $\frac{\partial S}{\partial \xi_{n(p)}} = 0$, one therefore gets: a minimum

$(S)_{\text{min.}} = -\sqrt{L} \simeq -1.563 \times 10^{-4} \left(\frac{V}{K} \right)$, and (iii) at $\xi_{n(p)} = 1$ one obtains:

$S \simeq -1.322 \times 10^{-4} \left(\frac{V}{K} \right)$.

Further, the figure of merit, ZT , is found to be defined by:

$$ZT(N, r_{d(a)}, x, T) \equiv \frac{S^2 \times \sigma \times T}{\kappa} = \frac{S^2}{L} = \frac{4 \times (ZT)_{\text{Mott}}}{[1 + (ZT)_{\text{Mott}}]^2}. \quad (20)$$

Here, one notes that: (i) $\frac{\partial(ZT)}{\partial \xi_{n(p)}} = 2 \times \frac{S}{L} \times \frac{\partial S}{\partial \xi_{n(p)}}$, $S < 0$, (ii) at $\xi_{n(p)} = \sqrt{\frac{\pi^2}{3}} \simeq 1.8138$, since $\frac{\partial(ZT)}{\partial \xi_{n(p)}} = 0$, one gets: a maximum $(ZT)_{\max} = 1$, and $(ZT)_{\text{Mott}} = 1$, and (iii) at $\xi_{n(p)} = 1$, one obtains: $ZT \simeq 0.715$ and $(ZT)_{\text{Mott}} = \frac{\pi^2}{3} \simeq 3.290$.

Finally, the first Van-Cong coefficient, VC1, can be defined by:

$$VC1(N, r_{d(a)}, x, T) \equiv -N^* \times \frac{dS}{dN^*} \left(\frac{V}{K} \right) = N^* \times \frac{\partial S}{\partial \xi_{n(p)}} \times -\frac{\partial \xi_{n(p)}}{\partial N^*}, \text{ being equal to 0 for } \xi_{n(p)} = \sqrt{\frac{\pi^2}{3}}, \quad (21)$$

$$\text{and the second Van-Cong coefficient, VC2, as: } VC2(N, r_{d(a)}, x, T) \equiv T \times VC1(V), \quad (22)$$

$$\text{the Thomson coefficient, Ts, by: } Ts(N, r_{d(a)}, x, T) \equiv T \times \frac{dS}{dT} \left(\frac{V}{K} \right) = T \times \frac{\partial S}{\partial \xi_{n(p)}} \times \frac{\partial \xi_{n(p)}}{\partial T}, \text{ being equal to 0 for } \xi_{n(p)} = \sqrt{\frac{\pi^2}{3}}, \quad (23)$$

$$\text{and the Peltier coefficient, Pt, as: } Pt(N, r_{d(a)}, x, T) \equiv T \times S(V). \quad (24)$$

One notes here that in next Tables 5n(p) and 6n(p) given in Appendix 1, obtained with such given physical conditions N(or T) for the decreasing $\xi_{n(p)}$, since $VC1(N, r_{d(a)}, x, T)$ and $Ts(N, r_{d(a)}, x, T)$ are expressed in terms of $\frac{-dS}{dN^*}$ and $\frac{dS}{dT}$, one has: $[VC1, Ts] < 0$ for $\xi_{n(p)} > \sqrt{\frac{\pi^2}{3}}$, $[VC1, Ts] = 0$ for $\xi_{n(p)} = \sqrt{\frac{\pi^2}{3}}$, and $[VC1, Ts] > 0$ for $\xi_{n(p)} < \sqrt{\frac{\pi^2}{3}}$, stating also that for $\xi_{n(p)} = \sqrt{\frac{\pi^2}{3}}$:

(i) S, determined in Eq. (19), thus presents **a same minimum** $(S)_{\min.} = -\sqrt{L} \simeq -1.563 \times 10^{-4} \left(\frac{V}{K} \right)$,

(ii) ZT, determined in Eq. (20), therefore presents **a same maximum**: $(ZT)_{\max} = 1$, since the variations of ZT are expressed in terms of $[VC1, Ts] \times S$, $S < 0$. Furthermore, it is interesting to remark that the (VC2)-coefficient is related to our generalized Einstein relation (17) by:

$$\frac{k_B}{q} \times VC2(N, r_{d(a)}, x, T) \equiv -\frac{\partial S}{\partial \xi_{n(p)}} \times \frac{D(N, r_{d(a)}, x, T)}{\mu(N, r_{d(a)}, x, T)} \left(\frac{V^2}{K} \right), \quad \frac{k_B}{q} = \sqrt{\frac{3 \times L}{\pi^2}}, \quad (25)$$

according, in this work, with the use of our Eq. (21), to:

$$sVC2(N, r_{d(a)}, x, T) \equiv -\frac{D(N, r_{d(a)}, x, T)}{\mu(N, r_{d(a)}, x, T)} \times 2 \times \frac{(ZT)_{\text{Mott}} \times [1 - (ZT)_{\text{Mott}}]}{[1 + (ZT)_{\text{Mott}}]^2} (V). \text{ Of course, our relation (25) is}$$

reduced to: $\frac{D}{\mu}$, VC1 and VC2, being determined respectively by Equations (17, 21, 22).

Now, in the degenerate n(p)-type X(x) – alloy, and for $N > N_{CDn(CDp)}$, and for $T=3K$ (80K), the numerical results of various thermoelectric coefficients are reported in Tables 4n(4p) in Appendix 1, noting that their variations with increasing $r_{d(a)}$ are represented by the arrows: ↗ (increase), and ↘ (decrease), respectively.

Then, in Tables 5n (5p) given Appendix 1 for a given N and with increasing T , and in Tables 6n(6p) given Appendix 1 for a given T and with decreasing N , the reduced Fermi-energy $\xi_{n(p)}$ decreases, and various thermoelectric coefficients are in variations, as indicated by the arrows as: (increase: ↗, decrease: ↘).

CONCLUDING REMARKS

Here, some concluding remarks can be given as follows.

(1) In the $n^+(p^+) - p(n) X(x) \equiv GaP_{1-x}Sb_x$ - crystalline alloy, $0 \leq x \leq 1$, the electrical-and-Mott criterium in the MIT is expressed in Equations (3, 5, 6), stating that the critical impurity density $N_{CDn(CDp)}$ is just the density of electrons (holes), localized in the exponential conduction (valence)-band thermoelectric laws, relations, and various coefficients are found to be enhanced by our static dielectric constant law, $\varepsilon(r_{d(a)}, x)$, being, for a given x , decreased with increasing $r_{d(a)}$, as given in Equations (1a, 1b) and also in Table 2 of our recent work (2024), by our accurate Fermi energy, $E_{Fn(Fp)}$, given in Eq. (11), and in particular by our electrical conductivity model given in Eq. (14).

(2) The generalized tail, $N_{CDn(CDp)}^{EBT}$, obtained with a precision of the order of 2.92×10^{-7} , as given in our previous work (2024), and the effective electron (hole)-density can be defined by: $N^* \equiv N - N_{CDn(CDp)} \simeq N - N_{CDn(CDp)}^{EBT}$, as that observed in the compensated crystals.

(3) The ratio of the inverse effective screening length $k_{sn(sp)}$ to Fermi wave number $k_{Fn(kp)}$ at 0 K, $R_{sn(sp)}(N^*)$, defined in Eq. (7), is valid for any density N^* .

(4) In Tables 5n (5p) given Appendix 1, for a given impurity density N and with increasing temperature T , and then in Tables 6n (6p) given Appendix 1, for a given T and with decreasing N , the reduced Fermi-energy $\xi_{n(p)}$ decreases, and other thermoelectric coefficients are in variations, as indicated by the arrows by: (increase: ↗, decrease: ↘). One remarks in these Tables that, for any given x , $r_{d(a)}$ and N (or T), with increasing T (or decreasing N), one obtains: (i) for $\xi_{n(p)} \simeq 1.8138$, while the numerical results of the Seebeck coefficient S present a **same minimum** $(S)_{min.} = -\sqrt{L} \simeq -1.563 \times 10^{-4} \left(\frac{V}{K}\right)$, those of the figure of merit ZT show a **same maximum** $(ZT)_{max.} = 1$, (ii) for $\xi_{n(p)} = 1$, the numerical results of S , ZT , the Mott figure of merit $(ZT)_{Mott}$, the Van-Cong coefficient $VC1$, and the Thomson coefficient Ts , present the same results: $-1.322 \times 10^{-4} \frac{V}{K}$, 0.715 , 3.290 , $1.105 \times 10^{-4} \frac{V}{K}$, and $1.657 \times 10^{-4} \frac{V}{K}$, respectively, and finally (iii) for $\xi_n \simeq 1.8138$, $(ZT)_{Mott} = 1$. It seems that

these same results could represent **a new law given for the thermoelectric properties, obtained in the degenerate case.**

(5) Finally, our electrical-and-thermoelectric relation is given in Eq. (25) by:

$$\frac{k_B}{q} \times VC2(N, r_{d(a)}, x, T) \equiv -\frac{\partial S}{\partial \xi_{n(p)}} \times \frac{D(N, r_{d(a)}, x, T)}{\mu(N, r_{d(a)}, x, T)} \left(\frac{V^2}{K} \right), \frac{k_B}{q} = \sqrt{\frac{3 \times 1}{\pi^2}}, \text{ according, in this work, to:}$$

$$VC2(N, r_{d(a)}, x, T) \equiv -\frac{D(N, r_{d(a)}, x, T)}{\mu(N, r_{d(a)}, x, T)} \times 2 \times \frac{(ZT)_{Mott} \times [1 - (ZT)_{Mott}]}{[1 + (ZT)_{Mott}]^2} \text{ (V), being reduced to: } \frac{D}{\mu}, VC1 \text{ and } VC2, \text{ determined respectively in Equations (17, 21, 22). This should be a new result.}$$

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APPENDIX 1: Tables

Table 1: The values of energy-band-structure parameters are given in the following.

In the $X(x) \equiv GaP_{1-x}Sb_x$ -crystalline alloy, in which $r_{do(ao)} = r_{P(Ga)} = 0.110$ nm (0.126 nm), we have: $g_{c(v)}(x) = 1 \times x + 1 \times (1-x)$, $m_{c(v)}(x)/m_o = 0.047 (0.3) \times x + 0.13 (0.5) \times (1-x)$, $\varepsilon_o(x) = 15.69 \times x + 11.1 \times (1-x)$, $E_{go}(x) = 0.81 \times x + 1.796 \times (1-x)$.

Table 2: Expressions for $G_{p \geq 1}(y \equiv \frac{\pi}{\xi_{n(p)}})$, due to the Fermi-Dirac distribution function, noting that $G_{p=1}(y \equiv \frac{\pi k_B T}{E_{Fn(Fp)}} = \frac{\pi}{\xi_{n(p)}}) = 1$, used to determine the electrical-and-thermoelectric coefficients.

$G_{3/2}(y)$	$G_2(y)$	$G_{5/2}(y)$	$G_3(y)$	$G_{7/2}(y)$	$G_4(y)$	$G_{9/2}(y)$
$(1 + \frac{y^2}{8} + \frac{7y^4}{640})$	$(1 + \frac{y^2}{3})$	$(1 + \frac{5y^2}{8} - \frac{7y^4}{384})$	$(1 + y^2)$	$(1 + \frac{35y^2}{24} + \frac{49y^4}{384})$	$(1 + 2y^2 + \frac{7y^4}{15})$	$(1 + \frac{21y^2}{8} + \frac{147y^4}{128})$

Table 3n: Here, one notes that, for given x , $N > N_{CDn}$ and $T(=4.2$ K and 77 K), the functions: σ, μ, μ_H, D , expressed respectively in $(\frac{10^2}{ohm \times cm}, \frac{10^3 \times cm^2}{V \times s}, \frac{10^3 \times cm^2}{V \times s}, \frac{10 \times cm^2}{s})$, decrease with increasing r_d .

Donor	P	As	Sb	Sn
r_d (nm)	0.110	0.118	0.136	0.140

For $x=0$, the values of (σ, μ, μ_H, D) at **4.2K**

$N (10^{18} \text{ cm}^{-3})$

3	6.57, 1.447, 1.448, 5.42	6.34, 1.403, 1.404, 5.23	4.62, 1.080, 1.081, 3.89	4.16, 0.997, 0.997, 3.53
10	17.0, 1.082, 1.082, 9.28	16.5, 1.049, 1.049, 8.99	12.6, 0.813, 0.813, 6.90	11.6, 0.753, 0.753, 6.36
40	50.7, 0.795, 0.795, 17.3	49.0, 0.768, 0.768, 16.7	37.2, 0.585, 0.585, 12.7	34.3, 0.540, 0.540, 11.7
70	79.8, 0.714, 0.714, 22.6	77.1, 0.689, 0.689, 21.8	57.9, 0.519, 0.519, 16.4	53.3, 0.478, 0.478, 15.1

For $x=0.5$, the values of (σ, μ, μ_H, D) at **4.2K**

$N (10^{18} \text{ cm}^{-3})$

3	9.60, 2.018, 2.019, 11.4	9.30, 1.956, 1.956, 11.1	7.06, 1.500, 1.500, 8.45	6.48, 1.381, 1.381, 7.76
10	24.2, 1.518, 1.518, 19.3	23.5, 1.472, 1.472, 18.7	18.1, 1.136, 1.136, 14.4	16.7, 1.051, 1.051, 13.3
40	72.2, 1.127, 1.127, 36.2	69.7, 1.089, 1.089, 35.0	52.8, 0.826, 0.826, 26.5	48.7, 0.761, 0.761, 24.4
70	114, 1.016, 1.016, 47.4	110, 0.981, 0.981, 45.7	82.4, 0.736, 0.736, 34.3	75.7, 0.676, 0.676, 31.5

For $x=1$, the values of (σ, μ, μ_H, D) at **4.2K**

$N (10^{18} \text{ cm}^{-3})$

3	14.9, 3.120, 3.121, 33.5	14.5, 3.024, 3.024, 32.5	11.1, 2.321, 2.321, 24.9	10.2, 2.138, 2.138, 23.0
10	37.7, 2.352, 2.352, 56.4	36.5, 2.279, 2.279, 54.7	28.1, 1.757, 1.757, 42.2	26.0, 1.625, 1.625, 39.0
40	113, 1.757, 1.757, 106	109, 1.698, 1.698, 103	82.2, 1.283, 1.283, 77.6	75.7, 1.182, 1.182, 71.5
70	178, 1.590, 1.590, 140	172, 1.534, 1.534, 135	128, 1.146, 1.146, 101	118, 1.052, 1.052, 92.4

For $x=0$, the values of (σ, μ, μ_H, D) at **77 K**

$N (10^{18} \text{ cm}^{-3})$

3	7.10, 1.566, 1.829, 5.75	6.86, 1.518, 1.776, 5.56	5.03, 1.176, 1.389, 4.14	4.54, 1.088, 1.291, 3.77
10	17.3, 1.098, 1.136, 9.39	16.7, 1.065, 1.102, 9.10	12.8, 0.825, 0.854, 6.98	11.8, 0.764, 0.792, 6.43
40	50.8, 0.797, 0.801, 17.4	49.1, 0.770, 0.774, 16.8	37.3, 0.587, 0.590, 12.7	34.4, 0.542, 0.545, 11.7
70	79.9, 0.714, 0.716, 22.6	77.2, 0.690, 0.692, 21.9	58.0, 0.520, 0.521, 16.4	53.3, 0.478, 0.479, 15.1

For $x=0.5$, the values of (σ, μ, μ_H, D) at **77 K**

$N (10^{18} \text{ cm}^{-3})$

3	9.94, 2.089, 2.250, 11.8	9.63, 2.025, 2.181, 11.4	7.32, 1.553, 1.674, 8.68	6.71, 1.430, 1.543, 7.98
10	24.4, 1.529, 1.553, 19.4	23.7, 1.482, 1.505, 18.8	18.2, 1.144, 1.162, 14.5	16.8, 1.059, 1.075, 13.4
40	72.2, 1.128, 1.131, 36.2	69.8, 1.090, 1.093, 35.0	52.9, 0.827, 0.829, 26.5	48.7, 0.762, 0.764, 24.4
70	114, 1.017, 1.018, 47.4	110, 0.981, 0.983, 45.8	82.5, 0.736, 0.737, 34.3	75.8, 0.676, 0.677, 31.5

For $x=1$, the values of (σ, μ, μ_H, D) at **77 K**

N (10^{18} cm^{-3})

3	15.1, 3.151, 3.220, 33.8	14.7, 3.054, 3.121, 32.7	11.2, 2.344, 2.395, 25.1	10.3, 2.159, 2.207, 23.1
10	37.7, 2.356, 2.367, 56.2	36.6, 2.283, 2.293, 54.8	28.2, 1.761, 1.769, 42.2	26.1, 1.629, 1.636, 39.0
40	113, 1.758, 1.759, 106	109, 1.698, 1.699, 103	82.2, 1.284, 1.284, 77.6	75.7, 1.182, 1.183, 71.5
70	178, 1.590, 1.590, 139	172, 1.534, 1.534, 135	128, 1.146, 1.147, 101	118, 1.052, 1.053, 92.4

Table 3p: Here, one notes that, for given x, $N > N_{CDP}$ and T(=4.2 K and 77 K), the

functions: σ, μ, μ_H, D , expressed respectively in $\left(\frac{10^3}{\text{ohm}\times\text{cm}}, \frac{10^2 \times \text{cm}^2}{\text{V}\times\text{s}}, \frac{10^2 \times \text{cm}^2}{\text{V}\times\text{s}}, \frac{10 \times \text{cm}^2}{\text{s}}\right)$,

decrease with increasing r_a .

Acceptor	Ga	Mg	In	Cd
r_a (nm)	0.126	0.140	0.144	0.148

For x=0, the values of (σ, μ, μ_H, D) at 4.2K

N (10^{19} cm^{-3})

3	1.27, 3.892, 3.894, 1.41	1.11, 3.699, 3.701, 1.26	1.00, 3.596, 3.598, 1.17	0.88, 3.491, 3.494, 1.07
5	2.15, 3.330, 3.331, 1.90	1.93, 3.123, 3.124, 1.73	1.80, 3.006, 3.007, 1.63	1.65, 2.879, 2.880, 1.52
8	3.34, 2.959, 2.959, 2.45	3.03, 2.755, 2.755, 2.24	2.85, 2.639, 2.639, 2.12	2.64, 2.510, 2.510, 1.99
10	4.08, 2.815, 2.815, 2.75	3.71, 2.614, 2.614, 2.53	3.50, 2.498, 2.499, 2.39	3.26, 2.371, 2.371, 2.24

For x=0.5, the values of (σ, μ, μ_H, D) at 4.2K

N (10^{19} cm^{-3})

3	2.77, 6.365, 6.366, 3.50	2.53, 5.908, 5.910, 3.21	2.38, 5.647, 5.648, 3.04	2.22, 5.357, 5.358, 2.85
5	4.34, 5.745, 5.746, 4.56	3.97, 5.307, 5.308, 4.18	3.75, 5.056, 5.057, 3.96	3.51, 4.777, 4.777, 3.72
8	6.54, 5.289, 5.290, 5.83	5.98, 4.869, 4.869, 5.34	5.66, 4.627, 4.627, 5.06	5.30, 4.358, 4.359, 4.74
10	7.95, 5.102, 5.103, 6.55	7.26, 4.689, 4.690, 6.00	6.87, 4.452, 4.452, 5.68	6.43, 4.189, 4.189, 5.33

For x=1, the values of (σ, μ, μ_H, D) at 4.2K

N (10^{19} cm^{-3})

3	5.72, 12.19, 12.19, 9.38	5.22, 11.19, 11.20, 8.59	4.94, 10.62, 10.62, 8.13	4.63, 9.988, 9.988, 7.62
5	8.94, 11.33, 11.33, 12.3	8.17, 10.37, 10.38, 11.3	7.72, 9.827, 9.827, 10.7	7.22, 9.217, 9.218, 9.99
8	13.5, 10.67, 10.67, 15.9	12.3, 9.748, 9.748, 14.5	11.7, 9.218, 9.218, 13.7	10.9, 8.630, 8.631, 12.9
10	16.5, 10.39, 10.39, 18.0	15.1, 9.484, 9.484, 16.4	14.2, 8.963, 8.963, 15.5	13.3, 8.385, 8.385, 14.5

For x=0, the values of (σ, μ, μ_H, D) at 77K

N (10^{19} cm^{-3})

3	1.38, 4.229, 4.983, 1.50	1.21, 4.061, 4.866, 1.36	1.11, 3.981, 4.839, 1.27	0.99, 3.920, 4.868, 1.17
5	2.23, 3.445, 3.706, 1.96	2.00, 3.238, 3.497, 1.78	1.87, 3.121, 3.382, 1.68	1.72, 2.996, 3.261, 1.57
8	3.39, 3.008, 3.118, 2.48	3.08, 2.802, 2.908, 2.27	2.90, 2.684, 2.789, 2.15	2.69, 2.555, 2.658, 2.01
10	4.12, 2.848, 2.923, 2.78	3.76, 2.645, 2.717, 2.55	3.54, 2.529, 2.599, 2.41	3.30, 2.401, 2.469, 2.26

For $x=0.5$, the values of (σ, μ, μ_H, D) at 77K

$N (10^{19} \text{ cm}^{-3})$

3	2.88, 6.603, 7.143, 3.60	2.62, 6.135, 6.650, 3.30	2.48, 5.868, 6.368, 3.13	2.30, 5.572, 6.058, 2.93
5	4.42, 5.848, 6.083, 4.62	4.04, 5.404, 5.624, 4.24	3.82, 5.149, 5.360, 4.02	3.57, 4.866, 5.068, 3.77
8	6.60, 5.338, 5.451, 5.87	6.04, 4.914, 5.018, 5.38	5.71, 4.670, 4.770, 5.10	5.35, 4.400, 4.494, 4.78
10	8.00, 5.137, 5.217, 6.59	7.31, 4.722, 4.795, 6.03	6.92, 4.483, 4.553, 5.71	6.48, 4.218, 4.284, 5.36

For $x=1$, the values of (σ, μ, μ_H, D) at 77K

$N (10^{19} \text{ cm}^{-3})$

3	5.82, 12.42, 12.95, 9.52	5.33, 11.41, 11.90, 8.71	5.04, 10.83, 11.29, 8.25	4.72, 10.18, 10.62, 7.74
5	9.03, 11.44, 11.68, 12.4	8.24, 10.47, 10.70, 11.4	7.79, 9.921, 10.13, 10.7	7.29, 9.305, 9.507, 10.1
8	13.6, 10.72, 10.85, 16.0	12.4, 9.797, 9.909, 14.6	11.7, 9.265, 9.371, 13.8	11.0, 8.674, 8.774, 12.9
10	16.6, 10.43, 10.52, 18.1	15.1, 9.520, 9.601, 16.5	14.3, 8.997, 9.073, 15.6	13.3, 8.416, 8.488, 14.6

Table 4n: In the lightly degenerate n-type $X(x)$ – alloy, and for $T=3K$ and $80K$, the numerical results of various thermoelectric coefficients are reported. Further, their variations with increasing $r_{d(a)}$ are represented by the arrows: ↗ (increase), and ↘ (decrease).

Donor		P	As	Sb	Sn
For $x=0$ and $N=3 \times 10^{18} \text{ cm}^{-3}$,					
$\xi_n(T=3K)$	↘	217.111	216.464	208.752	205.3606
$\xi_n(T=80K)$	↘	8.298	8.274	7.991	7.864
$\kappa_{(T=3K)} \left(\frac{10^{-5} \times W}{\text{cm} \times K} \right)$	↘	4.812	4.644	3.386	3.047
$\kappa_{(T=80K)} \left(\frac{10^{-3} \times W}{\text{cm} \times K} \right)$	↘	1.396	1.348	0.989	0.893
$s-S_{(T=3K)} \left(\frac{10^{-6} \times V}{K} \right)$	↘	2.611	2.619	2.716	2.761
$s-S_{(T=80K)} \left(\frac{10^{-5} \times V}{K} \right)$	↘	6.521	6.538	6.748	6.845
$-VC1_{(T=3K)} \left(\frac{10^{-6} \times V}{K} \right)$	↘	1.740	1.746	1.810	1.840
$-VC1_{(T=80K)} \left(\frac{10^{-5} \times V}{K} \right)$	↘	3.799	3.806	3.889	3.926
$-VC2_{(T=3K)} \left(\frac{10^{-6} \times V}{K} \right)$	↘	5.222	5.237	5.431	5.522
$-VC2_{(T=80K)} \left(\frac{10^{-3} \times V}{K} \right)$	↘	3.039	3.045	3.111	3.141

$-TS_{(T=3K)} \left(\frac{10^{-6} \times V}{K} \right)$	↘	2.611	2.619	2.715	2.761
$-TS_{(T=80K)} \left(\frac{10^{-5} \times V}{K} \right)$	↘	5.699	5.709	5.834	5.890
$-Pt_{(T=3K)} (10^{-6} \times V)$	↘	7.834	7.857	8.148	8.284
$-Pt_{(T=80K)} (10^{-3} \times V)$	↘	5.217	5.231	5.398	5.476
$ZT_{(T=3K)} (10^{-4})$	↗	2.791	2.808	3.019	3.121
$ZT_{(T=80K)} (10^{-1})$	↗	1.741	1.750	1.864	1.918

For $x=0.5$ and $N=3 \times 10^{18} \text{ cm}^{-3}$,

$\xi_n(T=3K)$	↘	329.220	329.052	327.067	326.190
$\xi_n(T=80K)$	↘	12.447	12.441	12.367	12.334
$\kappa_{(T=3K)} \left(\frac{10^{-5} \times W}{\text{cm} \times K} \right)$	↘	7.038	6.816	5.178	4.749
$\kappa_{(T=80K)} \left(\frac{10^{-3} \times W}{\text{cm} \times K} \right)$	↘	1.948	1.887	1.434	1.316
$s-S_{(T=3K)} \left(\frac{10^{-6} \times V}{K} \right)$	↘	1.722	1.723	1.733	1.738
$-S_{(T=80K)} \left(\frac{10^{-5} \times V}{K} \right)$	↘	4.460	4.463	4.488	4.499
$-VC1_{(T=3K)} \left(\frac{10^{-6} \times V}{K} \right)$	↘	1.148	1.149	1.155	1.159
$-VC1_{(T=80K)} \left(\frac{10^{-5} \times V}{K} \right)$	↘	2.803	2.804	2.818	2.824
$-VC2_{(T=3K)} \left(\frac{10^{-6} \times V}{K} \right)$	↘	3.444	3.446	3.467	3.476
$-VC2_{(T=80K)} \left(\frac{10^{-3} \times V}{K} \right)$	↘	2.242	2.243	2.254	2.259
$-TS_{(T=3K)} \left(\frac{10^{-6} \times V}{K} \right)$	↘	1.722	1.723	1.733	1.738
$-TS_{(T=80K)} \left(\frac{10^{-5} \times V}{K} \right)$	↘	4.204	4.206	4.227	4.236
$-Pt_{(T=3K)} (10^{-6} \times V)$	↘	5.166	5.169	5.200	5.214
$-Pt_{(T=80K)} (10^{-3} \times V)$	↘	3.568	3.570	3.590	3.600
$ZT_{(T=3K)} (10^{-4})$	↗	1.214	1.215	1.230	1.237
$ZT_{(T=80K)} (10^{-1})$	↗	0.814	0.815	0.824	0.829

For $x=1$ and $N=3 \times 10^{18} \text{ cm}^{-3}$,

$\xi_n(T=3K)$	↘	623.722	623.693	623.346	623.193
$\xi_n(T=80K)$	↘	23.442	23.441	23.428	23.423
$\kappa_{(T=3K)} \left(\frac{10^{-4} \times W}{\text{cm} \times K} \right)$	↘	1.098	1.064	0.816	0.751
$\kappa_{(T=80K)} \left(\frac{10^{-3} \times W}{\text{cm} \times K} \right)$	↘	2.959	2.868	2.199	2.025
$-S_{(T=3K)} \left(\frac{10^{-7} \times V}{K} \right)$	↘	9.090	9.091	9.096	9.098
$-S_{(T=80K)} \left(\frac{10^{-5} \times V}{K} \right)$	↘	2.404	2.405	2.406	2.407
$-VC1_{(T=3K)} \left(\frac{10^{-7} \times V}{K} \right)$	↘	6.060	6.061	6.064	6.065

$-VC1_{(T=80K)} \left(\frac{10^{-5} \times V}{K} \right) \searrow$	1.576	1.577	1.578	1.579
$-VC2_{(T=3K)} \left(\frac{10^{-6} \times V}{K} \right) \searrow$	1.818	1.819	1.820	1.820
$-VC2_{(T=80K)} \left(\frac{10^{-3} \times V}{K} \right) \searrow$	1.261	1.262	1.263	1.264
$-TS_{(T=3K)} \left(\frac{10^{-7} \times V}{K} \right) \searrow$	9.090	9.091	9.096	9.098
$-TS_{(T=80K)} \left(\frac{10^{-5} \times V}{K} \right) \searrow$	2.365	2.366	2.367	2.368
$-Pt_{(T=3K)}(10^{-6} \times V) \searrow$	2.727	2.728	2.729	2.730
$-Pt_{(T=80K)}(10^{-3} \times V) \searrow$	1.923	1.924	1.925	1.926
$ZT_{(T=3K)}(10^{-5}) \nearrow$	3.382	3.383	3.387	3.388
$ZT_{(T=80K)}(10^{-2}) \nearrow$	2.366	2.367	2.369	2.370

Table 4p: In the lightly degenerate p-type X(x) – alloy, in which $N=2 \times 10^{19} \text{ cm}^{-3}$, and for $T=3K$ and $80K$, the numerical results of various thermoelectric coefficients are reported. Further, their variations with increasing $r_{d(a)}$ are represented by the arrows: $\nearrow$ (increase), and $\searrow$ (decrease).

Acceptor		Ga	Mg	In	Cds
For x=0,					
$\xi_n(T=3K) \searrow$		134.452	119.021	107.417	90.933
$\xi_n(T=80K) \searrow$		5.283	4.706	4.241	3.483
$\kappa_{(T=3K)} \left(\frac{10^{-5} \times W}{\text{cm} \times K} \right) \searrow$		5.576	4.510	3.828	2.983
$\kappa_{(T=80K)} \left(\frac{10^{-3} \times W}{\text{cm} \times K} \right) \searrow$		1.824	1.535	1.338	1.054
$s-S_{(T=3K)} \left(\frac{10^{-6} \times V}{K} \right) \searrow$		4.216	4.763	5.277	6.233
$-S_{(T=80K)} \left(\frac{10^{-5} \times V}{K} \right) \searrow$		9.601	10.490	11.301	12.806
$-VC1_{(T=3K)} \left(\frac{10^{-6} \times V}{K} \right) \searrow$		2.809	3.173	3.515	4.151
$-VC1_{(T=80K)} \left(\frac{10^{-5} \times V}{K} \right) \searrow$		4.716	5.044	5.530	6.430
$-VC2_{(T=3K)} \left(\frac{10^{-6} \times V}{K} \right) \searrow$		8.428	9.519	10.545	12.452
$-VC2_{(T=80K)} \left(\frac{10^{-3} \times V}{K} \right) \searrow$		3.772	4.035	4.424	5.144
$-TS_{(T=3K)} \left(\frac{10^{-6} \times V}{K} \right) \searrow$		4.214	4.760	5.273	6.226
$-TS_{(T=80K)} \left(\frac{10^{-5} \times V}{K} \right) \searrow$		7.073	7.567	8.295	9.646
$-Pt_{(T=3K)}(10^{-5} \times V) \searrow$		1.265	1.429	1.583	1.870
$-Pt_{(T=80K)}(10^{-3} \times V) \searrow$		7.681	8.392	9.041	10.245

$ZT_{(T=3K)} (10^{-4})$	↗	7.277	9.285	11.398	15.902
$ZT_{(T=80K)} (10^{-1})$	↗	3.773	4.505	5.228	6.713

For $x=0.5$,

$\xi_n(T=3K)$	↘	234.965	230.328	227.003	222.546
$\xi_n(T=80K)$	↘	8.955	8.784	8.662	s8.497
$\kappa_{(T=3K)} \left(\frac{10^{-5} \times W}{cm \times K} \right)$	↘	14.107	12.775	11.988	11.088
$\kappa_{(T=80K)} \left(\frac{10^{-3} \times W}{cm \times K} \right)$	↘	4.045	3.673	3.454	3.205
$-S_{(T=3K)} \left(\frac{10^{-6} \times V}{K} \right)$	↘	2.413	2.461	2.497	2.547
$-S_{(T=80K)} \left(\frac{10^{-5} \times V}{K} \right)$	↘	6.082	6.191	6.271	6.382
$-VC1_{(T=3K)} \left(\frac{10^{-6} \times V}{K} \right)$	↘	1.608	1.641	1.665	1.698
$-VC1_{(T=80K)} \left(\frac{10^{-5} \times V}{K} \right)$	↘	3.612	3.660	3.695	3.741
$-VC2_{(T=3K)} \left(\frac{10^{-6} \times V}{K} \right)$	↘	4.825	4.922	4.994	5.094
$-VC2_{(T=80K)} \left(\frac{10^{-3} \times V}{K} \right)$	↘	2.890	2.928	2.956	2.993
$-TS_{(T=3K)} \left(\frac{10^{-6} \times V}{K} \right)$	↘	2.412	2.461	2.497	2.547
$-TS_{(T=80K)} \left(\frac{10^{-5} \times V}{K} \right)$	↘	5.419	5.490	5.542	5.612
$-Pt_{(T=3K)} (10^{-5} \times V)$	↘	0.724	0.738	0.749	0.764
$-Pt_{(T=80K)} (10^{-3} \times V)$	↘	4.866	4.953	5.017	5.105
$ZT_{(T=3K)} (10^{-4})$	↗	2.383	2.480	2.553	2.657
$ZT_{(T=80K)} (10^{-1})$	↗	1.514	1.569	1.610	1.667

For $x=1$,

$\xi_n(T=3K)$	↘	337.828	336.27	335.162	333.685
$\xi_n(T=80K)$	↘	12.767	12.709	12.668	12.613
$\kappa_{(T=3K)} \left(\frac{10^{-5} \times W}{cm \times K} \right)$	↘	29.427	26.908	25.451	23.823
$\kappa_{(T=80K)} \left(\frac{10^{-3} \times W}{cm \times K} \right)$	↘	8.130	7.437	7.036	6.588
$-S_{(T=3K)} \left(\frac{10^{-6} \times V}{K} \right)$	↘	1.678	1.686	1.692	1.699
$-S_{(T=80K)} \left(\frac{10^{-5} \times V}{K} \right)$	↘	4.353	4.372	4.386	4.404
$-VC1_{(T=3K)} \left(\frac{10^{-6} \times V}{K} \right)$	↘	1.119	1.124	1.128	1.133
$-VC1_{(T=80K)} \left(\frac{10^{-5} \times V}{K} \right)$	↘	2.743	2.754	2.762	2.772
$-VC2_{(T=3K)} \left(\frac{10^{-6} \times V}{K} \right)$	↘	3.356	3.372	3.383	3.398
$-VC2_{(T=80K)} \left(\frac{10^{-3} \times V}{K} \right)$	↘	2.195	2.203	2.209	2.217

$-TS_{(T=3K)} \left(\frac{10^{-6} \times V}{K} \right)$	↘	1.678	1.686	1.691	1.699
$-TS_{(T=80K)} \left(\frac{10^{-5} \times V}{K} \right)$	↘	4.115	4.131	4.142	4.158
$-Pt_{(T=3K)} (10^{-5} \times V)$	↘	0.503	0.506	0.507	0.510
$-Pt_{(T=80K)} (10^{-3} \times V)$	↘	3.482	3.498	3.509	3.523
$ZT_{(T=3K)} (10^{-4})$	↗	1.153	1.164	1.171	1.182
$ZT_{(T=80K)} (10^{-1})$	↗	0.776	0.782	0.787	0.794

Table 5n: Here, for a given N and with increasing T , the reduced Fermi-energy ξ_n decreases, and other thermoelectric coefficients are in variations, as indicated by the arrows as: (increase: ↗, decrease: ↘). One notes here that with increasing T : (i) for $\xi_n \simeq 1.8138$, while the numerical results of S present a same minimum $(S)_{\min.} \left(\simeq -1.563 \times 10^{-4} \frac{V}{K} \right)$, those of ZT show a same maximum $(ZT)_{\max} = 1$, (ii) for $\xi_n = 1$, those of S , ZT , $(ZT)_{\text{Mott}}$, $VC1$, and T_s present the same results: $-1.322 \times 10^{-4} \frac{V}{K}$, 0.715 , 3.290 , $1.105 \times 10^{-4} \frac{V}{K}$ and $1.657 \times 10^{-4} \frac{V}{K}$, respectively, and (iii) for $\xi_n \simeq 1.8138$, $(ZT)_{\text{Mott}} = 1$.

For $x=0$,

In the degenerate P-X(x) – alloy, for $N = 2 \times N_{\text{CDn}}(r_p) = 3.3719916 \times 10^{17} \text{ cm}^{-3}$, one gets:

$T(K)$	↗	43.85	44.769183	45.7	60.920214	60.945
ξ_n	↘	1.877	1.8138	1.752	1	0.999
$S \left(10^{-4} \frac{V}{K} \right)$		-1.562	↘ -1.563	↗ -1.562	↗ -1.322	↗ -1.321
ZT		0.999	↗ 1	↘ 0.999	↘ 0.715	↘ 0.714
$(ZT)_{\text{Mott}}$	↗	0.933	1	1.071	3.290	3.296
$VC1 \left(10^{-4} \frac{V}{K} \right)$		-0.059	↗ 0	↗ 0.061	↗ 1.105	↗ 1.106
$VC2 \left(10^{-4} \frac{V}{K} \right)$		-2.590	↗ 0	↗ 2.778	↗ 67.313	↗ 67.440
$T_s \left(10^{-4} \frac{V}{K} \right)$		-0.089	↗ 0	↗ 0.091	↗ 1.657	↗ 1.660
$Pt (10^{-3} V)$		-6.850	↘ -6.997	↘ -7.139	↘ -8.0518	↘ -8.0510

In the degenerate As-X(x) – alloy, for $N = 2 \times N_{\text{CDn}}(r_{\text{As}}) = 3.6247868 \times 10^{17} \text{ cm}^{-3}$, one gets:

$T(K)$	↗	45.98	46.979655	47.99	63.928142	63.955
ξ_n	↘	1.880	1.8138	1.750	1	0.999
$S \left(10^{-4} \frac{V}{K} \right)$		-1.562	↘ -1.563	↗ -1.562	↗ -1.322	↗ -1.321
ZT		0.999	↗ 1	↘ 0.999	↘ 0.715	↘ 0.714
$(ZT)_{\text{Mott}}$	↗	0.931	1	1.074	3.290	3.296
$VC1 \left(10^{-4} \frac{V}{K} \right)$		-0.061	↗ 0	↗ 0.063	↗ 1.105	↗ 1.107
$VC2 \left(10^{-4} \frac{V}{K} \right)$		-2.814	↗ 0	↗ 3.018	↗ 70.637	↗ 70.774
$T_s \left(10^{-4} \frac{V}{K} \right)$		-0.092	↗ 0	↗ 0.094	↗ 1.657	↗ 1.660
$Pt (10^{-3} V)$		-7.182	↘ -7.343	↘ -7.496	↘ -8.4494	↘ -8.4485

In the degenerate Sb- X(x) – alloy, for $N = 2 \times N_{CDn}(r_{Sb}) = 6.6108594 \times 10^{17} \text{ cm}^{-3}$, one gets:

T(K)	↗	68.64	70.128324	71.63	95.427976	95.468
ξ_n	↘	1.879	1.8138	1.750	1	0.999
$S\left(10^{-4} \frac{V}{K}\right)$		-1.562	↘ -1.563	↗ -1.562	↗ -1.322	↗ -1.321
ZT		0.999	↗ 1	↘ 0.999	↘ 0.715	↘ 0.714
(ZT) _{Mott}	↗	0.931	1	1.074	3.290	3.296
$VC1\left(10^{-4} \frac{V}{K}\right)$		-0.061	↗ 0	↗ 0.063	↗ 1.105	↗ 1.107
$VC2\left(10^{-4} \frac{V}{K}\right)$		-4.190	↗ 0	↗ 4.485	↗ 105.443	↗ 105.647
$T_s\left(10^{-4} \frac{V}{K}\right)$		-0.091	↗ 0	↗ 0.094	↗ 1.657	↗ 1.660
Pt ($10^{-3}V$)		-10.722	↘ -10.961	↘ -11.189	↘ -12.613	↗ -12.6114

In the degenerate Sn- X(x) – alloy, for $N = 2 \times N_{CDn}(r_{Sn}) = 7.9274126 \times 10^{17} \text{ cm}^{-3}$, one gets:

T(K)	↗	77.47	79.154538	80.85	107.71051	107.82
ξ_n	↘	1.880	1.8138	1.750	1	0.998
$S\left(10^{-4} \frac{V}{K}\right)$		-1.562	↘ -1.563	↗ -1.562	↗ -1.322	↗ -1.320
ZT		0.999	↗ 1	↘ 0.999	↘ 0.715	↘ 0.713
(ZT) _{Mott}	↗	0.931	1	1.074	3.290	3.306
$VC1\left(10^{-4} \frac{V}{K}\right)$		-0.061	↗ 0	↗ 0.063	↗ 1.105	↗ 1.109
$VC2\left(10^{-4} \frac{V}{K}\right)$		-4.742	↗ 0	↗ 5.064	↗ 119.014	↗ 119.574
$T_s\left(10^{-4} \frac{V}{K}\right)$		-0.092	↗ 0	↗ 0.094	↗ 1.657	↗ 1.663
Pt ($10^{-3}V$)		-12.101	↘ -12.372	↘ -12.629	↘ -14.236	↗ -14.232

For $x=0.5$,

In the degenerate P- X(x) – alloy, for $N = 2 \times N_{CDn}(r_P) = 6.0537854 \times 10^{16} \text{ cm}^{-3}$, one gets:

T(K)	↗	20.4822	20.9285725	21.3788	28.478812	28.507
ξ_n	↘	1.880	1.8138	1.750	1	0.998
$S\left(10^{-4} \frac{V}{K}\right)$		-1.562	↘ -1.563	↗ -1.562	↗ -1.322	↗ -1.320
ZT		0.999	↗ 1	↘ 0.999	↘ 0.715	↘ 0.713
(ZT) _{Mott}	↗	0.931	1	1.074	3.290	3.305
$VC1\left(10^{-4} \frac{V}{K}\right)$		-0.061	↗ 0	↗ 0.063	↗ 1.105	↗ 1.109
$VC2\left(10^{-4} \frac{V}{K}\right)$		-1.256	↗ 0	↗ 1.345	↗ 31.467	↗ 31.612
$T_s\left(10^{-4} \frac{V}{K}\right)$		-0.092	↗ 0	↗ 0.094	↗ 1.657	↗ 1.663
Pt ($10^{-3}V$)		-3.199	↘ -3.271	↘ -3.339	↘ -3.7640	↗ -3.7631

In the degenerate As- X(x) – alloy, for $N = 2 \times N_{CDn}(r_{As}) = 6.5076322 \times 10^{16} \text{ cm}^{-3}$, one gets:

T(K)	↗	21.4935	21.961918	22.4344	29.884949	29.9156
ξ_n	↘	1.880	1.8138	1.750	1	0.997
$S\left(10^{-4} \frac{V}{K}\right)$		-1.562	↘ -1.563	↗ -1.562	↗ -1.322	↗ -1.320
ZT		0.999	↗ 1	↘ 0.999	↘ 0.715	↘ 0.713
(ZT) _{Mott}	↗	0.931	1	1.074	3.290	3.306
$VC1\left(10^{-4} \frac{V}{K}\right)$		-0.061	↗ 0	↗ 0.063	↗ 1.105	↗ 1.109
$VC2\left(10^{-4} \frac{V}{K}\right)$		-1.318	↗ 0	↗ 1.411	↗ 33.021	↗ 33.178
$T_s\left(10^{-4} \frac{V}{K}\right)$		-0.092	↗ 0	↗ 0.094	↗ 1.657	↗ 1.663
Pt ($10^{-3}V$)		-3.357	↘ -3.433	↘ -3.504	↘ -3.9499	↗ -3.9489

In the degenerate Sb- X(x) – alloy, for $N = 2 \times N_{CDn}(r_{Sb}) = 1.1868572 \times 10^{17} \text{ cm}^{-3}$, one gets:

T(K)	↗	32.0842	32.783393	↘	33.486	44.610405	↘	44.656
ξ_n	↘	1.880	1.8138	↗	1.750	1	↗	0.998
$S \left(10^{-4} \frac{V}{K} \right)$	↗	-1.562	↘ -1.563	↗	-1.562	↗ -1.322	↗	-1.320
ZT	↗	0.999	1	↘	0.999	↘ 0.715	↘	0.713
$(ZT)_{Mott}$	↗	0.931	1	↘	1.074	3.290	↘	3.306
$VC1 \left(10^{-4} \frac{V}{K} \right)$	↗	-0.061	0	↗	0.063	1.105	↗	1.109
$VC2 \left(10^{-4} \frac{V}{K} \right)$	↗	-1.968	0	↗	2.099	49.292	↗	49.525
$T_s \left(10^{-4} \frac{V}{K} \right)$	↗	-0.092	0	↗	0.094	1.657	↗	1.663
Pt ($10^{-3}V$)	↘	-5.011	↘ -5.124	↘	-5.230	↘ -5.8962	↘	-5.8946

In the degenerate Sn- X(x) – alloy, for $N = 2 \times N_{CDn}(r_{Sn}) = 1.4232199 \times 10^{17} \text{ cm}^{-3}$, one gets:

T(K)	↗	36.2138	37.002943	↘	37.799	50.352208	↘	50.403
ξ_n	↘	1.880	1.8138	↗	1.750	1	↗	0.998
$S \left(10^{-4} \frac{V}{K} \right)$	↗	-1.562	↘ -1.563	↗	-1.562	↗ -1.322	↗	-1.320
ZT	↗	0.999	1	↘	0.999	↘ 0.715	↘	0.713
$(ZT)_{Mott}$	↗	0.931	1	↘	1.074	3.290	↘	3.305
$VC1 \left(10^{-4} \frac{V}{K} \right)$	↗	-0.061	0	↗	0.063	1.105	↗	1.109
$VC2 \left(10^{-4} \frac{V}{K} \right)$	↗	-2.221	0	↗	2.378	55.636	↗	55.896
$T_s \left(10^{-4} \frac{V}{K} \right)$	↗	-0.092	0	↗	0.094	1.657	↗	1.663
Pt ($10^{-3}V$)	↘	-5.656	↘ -5.783	↘	-5.904	↘ -6.6551	↘	-6.6533

For x=1,

In the degenerate P- X(x) – alloy, for $N = 2 \times N_{CDn}(r_P) = 5.6422212 \times 10^{15} \text{ cm}^{-3}$, one gets:

T(K)	↗	7.92813	8.100909	↘	8.275	11.023411	↘	11.0347
ξ_n	↘	1.880	1.8138	↗	1.750	1	↗	0.998
$S \left(10^{-4} \frac{V}{K} \right)$	↗	-1.562	↘ -1.563	↗	-1.562	↗ -1.322	↗	-1.320
ZT	↗	0.999	1	↘	0.999	↘ 0.715	↘	0.713
$(ZT)_{Mott}$	↗	0.931	1	↘	1.074	3.290	↘	3.306
$VC1 \left(10^{-4} \frac{V}{K} \right)$	↗	-0.061	0	↗	0.063	1.105	↗	1.109
$VC2 \left(10^{-4} \frac{V}{K} \right)$	↗	-0.486	0	↗	0.520	12.180	↗	12.238
$T_s \left(10^{-4} \frac{V}{K} \right)$	↗	-0.092	0	↗	0.094	1.657	↗	1.663
Pt ($10^{-3}V$)	↘	-1.238	↘ -1.266	↘	-1.292	↘ -1.4570	↘	-1.4566

In the degenerate As- X(x) – alloy, for $N = 2 \times N_{CDn}(r_{As}) = 6.0652134 \times 10^{15} \text{ cm}^{-3}$, one gets:

T(K)	↗	8.3196	8.50088993	↘	8.6837	11.5676903	↘	11.579
ξ_n	↘	1.880	1.8138	↗	1.750	1	↗	0.998
$S \left(10^{-4} \frac{V}{K} \right)$	↗	-1.562	↘ -1.563	↗	-1.562	↗ -1.322	↗	-1.320
ZT	↗	0.999	1	↘	0.999	↘ 0.715	↘	0.713
$(ZT)_{Mott}$	↗	0.931	1	↘	1.074	3.290	↘	3.305
$VC1 \left(10^{-4} \frac{V}{K} \right)$	↗	-0.061	0	↗	0.063	1.105	↗	1.109
$VC2 \left(10^{-4} \frac{V}{K} \right)$	↗	-0.510	0	↗	0.546	12.782	↗	12.839
$T_s \left(10^{-4} \frac{V}{K} \right)$	↗	-0.092	0	↗	0.094	1.657	↗	1.663
Pt ($10^{-3}V$)	↘	-1.299	↘ -1.329	↘	-1.356	↘ -1.5289	↘	-1.5285

In the degenerate Sb- X(x) – alloy, for $N = 2 \times N_{CDn}(r_{Sb}) = 1.1061692 \times 10^{16} \text{ cm}^{-3}$, one gets:								
T(K)	↗	12.419	12.689603		12.962	17.267533		17.285
ξ_n	↘	1.880	1.8138		1.750	1		0.998
$S \left(10^{-4} \frac{V}{K} \right)$		-1.562	↘ -1.563	↗	-1.562	↗ -1.322	↗	-1.320
ZT		0.999	↗ 1	↘	0.999	↘ 0.715	↘	0.713
$(ZT)_{Mott}$	↗	0.931	1		1.074	3.290		3.305
$VC1 \left(10^{-4} \frac{V}{K} \right)$		-0.061	↗ 0	↗	0.063	↗ 1.105	↗	1.109
$VC2 \left(10^{-4} \frac{V}{K} \right)$		-0.762	↗ 0	↗	0.814	↗ 19.080	↗	19.169
$T_s \left(10^{-4} \frac{V}{K} \right)$		-0.092	↗ 0	↗	0.094	↗ 1.657	↗	1.663
Pt ($10^{-3} V$)		-1.940	↘ -1.983	↘	-2.025	↘ -2.2822	↗	-2.2817
In the degenerate Sn- X(x) – alloy, for $N = 2 \times N_{CDn}(r_{Sn}) = 1.3264628 \times 10^{16} \text{ cm}^{-3}$, one gets:								
T(K)	↗	14.018	14.3228814		14.6299	19.490037		19.51
ξ_n	↘	1.880	1.8138		1.750	1		0.998
$S \left(10^{-4} \frac{V}{K} \right)$		-1.562	↘ -1.563	↗	-1.562	↗ -1.322	↗	-1.320
ZT		0.999	↗ 1	↘	0.999	↘ 0.715	↘	0.713
$(ZT)_{Mott}$	↗	0.931	1		1.074	3.290		3.306
$VC1 \left(10^{-4} \frac{V}{K} \right)$		-0.061	↗ 0	↗	0.063	↗ 1.105	↗	1.109
$VC2 \left(10^{-4} \frac{V}{K} \right)$		-0.858	↗ 0	↗	0.917	↗ 21.535	↗	21.637
$T_s \left(10^{-4} \frac{V}{K} \right)$		-0.092	↗ 0	↗	0.094	↗ 1.657	↗	1.663
Pt ($10^{-3} V$)		-2.190	↘ -2.239	↘	-2.285	↘ -2.5760	↗	-2.5753

Table 5p: Here, for a given N and with increasing T, the reduced Fermi-energy ξ_p decreases, and other thermoelectric coefficients are in variations, as indicated by the arrows as: (increase: ↗, decrease: ↘). One notes here that with increasing T: (i) for $\xi_p \simeq 1.8138$, while the numerical results of S present a same minimum $(S)_{min} \left(\simeq -1.563 \times 10^{-4} \frac{V}{K} \right)$, those of ZT show a same maximum $(ZT)_{max} = 1$, (ii) for $\xi_p = 1$, those of S, ZT, $(ZT)_{Mott}$, VC1, and T_s present the same results: $-1.322 \times 10^{-4} \frac{V}{K}$, 0.715, 3.290, $1.105 \times 10^{-4} \frac{V}{K}$ and $1.657 \times 10^{-4} \frac{V}{K}$, respectively, and (iii) for $\xi_p \simeq 1.8138$, $(ZT)_{Mott} = 1$.

For $x=0$,

In the degenerate Ga- X(x) – alloy, for $N = 2 \times N_{CDp}(r_{Ga}) = 1.9185205 \times 10^{19} \text{ cm}^{-3}$, one gets:

T(K)	↗	168.52	172.18917		175.88	234.30852		234.54
ξ_p	↘	1.880	1.8138		1.750	1		0.998
$S \left(10^{-4} \frac{V}{K} \right)$		-1.562	↘ -1.563	↗	-1.562	↗ -1.322	↗	-1.320
ZT		0.999	↗ 1	↘	0.998	↘ 0.715	↘	0.713
$(ZT)_{Mott}$	↗	0.931	1		1.074	3.290		3.305
$VC1 \left(10^{-4} \frac{V}{K} \right)$		-0.061	↗ 0	↗	0.063	↗ 1.105	↗	1.109
$VC2 \left(10^{-2} \frac{V}{K} \right)$		-0.103	↗ 0	↗	0.110	↗ 2.589	↗	2.601
$T_s \left(10^{-4} \frac{V}{K} \right)$		-0.092	↗ 0	↗	0.094	↗ 1.657	↗	1.663
Pt ($10^{-2} V$)		-2.632	↘ -2.691	↘	-2.747	↘ -3.0969	↗	-3.0961

In the degenerate Mg- $X(x)$ – alloy, for $N = 2 \times N_{CDP}(r_{Mg}) = 2.2664086 \times 10^{19} \text{ cm}^{-3}$, one gets:

T(K)	↗	188.32	192.42153	↘	196.55	261.83996	↘	262.1
ξ_p	↘	1.880	1.8138	↗	1.750	1	↗	0.998
$S\left(10^{-4}\frac{V}{K}\right)$	↗	-1.562	↘ -1.563	↗	-1.562	↘ -1.322	↗	-1.320
ZT	↗	0.999	1	↘	0.999	↘ 0.715	↗	0.713
$(ZT)_{Mott}$	↗	0.931	1	↘	1.074	3.290	↗	3.305
$VC1\left(10^{-4}\frac{V}{K}\right)$	↗	-0.061	0	↘	0.063	1.105	↗	1.109
$VC2\left(10^{-2}\frac{V}{K}\right)$	↗	-0.115	0	↘	0.123	2.893	↗	2.906
$T_s\left(10^{-4}\frac{V}{K}\right)$	↗	-0.092	0	↘	0.094	1.657	↗	1.663
Pt ($10^{-2}V$)	↗	-2.941	↘ -3.007	↗	-3.070	↘ -3.4607	↗	-3.4599

In the degenerate In- $X(x)$ – alloy, for $N = 2 \times N_{CDP}(r_{In}) = 2.5136974 \times 10^{19} \text{ cm}^{-3}$, one gets:

T(K)	↗	201.78	206.175403	↘	210.59	280.55571	↘	280.83
ξ_p	↘	1.880	1.8138	↗	1.750	1	↗	0.998
$S\left(10^{-4}\frac{V}{K}\right)$	↗	-1.562	↘ -1.563	↗	-1.562	↘ -1.322	↗	-1.320
ZT	↗	0.999	1	↘	0.999	↘ 0.715	↗	0.713
$(ZT)_{Mott}$	↗	0.931	1	↘	1.074	3.290	↗	3.305
$VC1\left(10^{-4}\frac{V}{K}\right)$	↗	-0.061	0	↘	0.063	1.105	↗	1.109
$VC2\left(10^{-2}\frac{V}{K}\right)$	↗	-0.124	0	↘	0.132	3.100	↗	3.114
$T_s\left(10^{-4}\frac{V}{K}\right)$	↗	-0.092	0	↘	0.094	1.657	↗	1.663
Pt ($10^{-2}V$)	↗	-3.152	↘ -3.222	↗	-3.289	↘ -3.7081	↗	-3.7072

In the degenerate Cd- $X(x)$ – alloy, for $N = 2 \times N_{CDP}(r_{Cd}) = 2.842425 \times 10^{19} \text{ cm}^{-3}$, one gets:

T(K)	↗	219.02	223.779792	↘	228.58	304.5111	↘	304.82
ξ_p	↘	1.880	1.8138	↗	1.750	1	↗	0.998
$S\left(10^{-4}\frac{V}{K}\right)$	↗	-1.562	↘ -1.563	↗	-1.562	↘ -1.322	↗	-1.320
ZT	↗	0.999	1	↘	0.999	↘ 0.715	↗	0.713
$(ZT)_{Mott}$	↗	0.931	1	↘	1.074	3.290	↗	3.305
$VC1\left(10^{-4}\frac{V}{K}\right)$	↗	-0.061	0	↘	0.063	1.105	↗	1.109
$VC2\left(10^{-2}\frac{V}{K}\right)$	↗	-0.134	0	↘	0.143	3.365	↗	3.380
$T_s\left(10^{-4}\frac{V}{K}\right)$	↗	-0.092	0	↘	0.094	1.657	↗	1.663
Pt ($10^{-2}V$)	↗	-3.421	↘ -3.498	↗	-3.570	↘ -4.0247	↗	-4.0237

For $x=0.5$,

In the degenerate Ga- $X(x)$ – alloy, for $N = 2 \times N_{CDP}(r_{Ga}) = 5.5895544 \times 10^{18} \text{ cm}^{-3}$, one gets:

T(K)	↗	92.575	94.59242	↘	96.627	128.717794	↘	128.849
ξ_p	↘	1.880	1.8138	↗	1.750	1	↗	0.998
$S\left(10^{-4}\frac{V}{K}\right)$	↗	-1.562	↘ -1.563	↗	-1.562	↘ -1.322	↗	-1.320
ZT	↗	0.999	1	↘	0.998	↘ 0.715	↗	0.713
$(ZT)_{Mott}$	↗	0.931	1	↘	1.074	3.290	↗	3.306
$VC1\left(10^{-4}\frac{V}{K}\right)$	↗	-0.061	0	↘	0.063	1.105	↗	1.109
$VC2\left(10^{-2}\frac{V}{K}\right)$	↗	-0.057	0	↘	0.061	1.422	↗	1.429
$T_s\left(10^{-4}\frac{V}{K}\right)$	↗	-0.092	0	↘	0.094	1.657	↗	1.663
Pt ($10^{-2}V$)	↗	-1.446	↘ -1.478	↗	-1.509	↘ -1.7013	↗	-1.7008

In the degenerate Mg- $X(x)$ – alloy, for $N = 2 \times N_{CDP}(r_{Mg}) = 6.6031166 \times 10^{18} \text{ cm}^{-3}$, one gets:

T(K)	↗	103.46	105.707108	↘	107.981	143.84224	↘	143.989
ξ_p	↘	1.880	1.8138	↗	1.750	1	↗	0.998

$S \left(10^{-4} \frac{V}{K} \right)$	-1.562	↘	-1.563	↗	-1.562	↗	-1.322	↗	-1.320
ZT	0.999	↗	1	↘	0.998	↘	0.715	↘	0.713
$(ZT)_{Mott}$	0.931	↗	1		1.074		3.290		3.306
$VC1 \left(10^{-4} \frac{V}{K} \right)$	-0.061	↗	0	↗	0.063	↗	1.105	↗	1.109
$VC2 \left(10^{-2} \frac{V}{K} \right)$	-0.063	↗	0	↗	0.068	↗	1.589	↗	1.597
$T_s \left(10^{-4} \frac{V}{K} \right)$	-0.092	↗	0	↗	0.094	↗	1.657	↗	1.663
Pt ($10^{-2}V$)	-1.616	↘	-1.652	↘	-1.687	↘	-1.9012	↗	-1.9007

In the degenerate In- X(x) – alloy, for $N = 2 \times N_{CDP}(r_{In}) = 7.323585 \times 10^{18} \text{ cm}^{-3}$, one gets:

T(K)	↗	110.85	113.262816		115.69		154.12377		154.28
ξ_p	↘	1.880	1.8138		1.750		1		0.998
$S \left(10^{-4} \frac{V}{K} \right)$	-1.562	↘	-1.563	↗	-1.562	↗	-1.322	↗	-1.320
ZT	0.999	↗	1	↘	0.999	↘	0.715	↘	0.713
$(ZT)_{Mott}$	0.931	↗	1		1.074		3.290		3.305
$VC1 \left(10^{-4} \frac{V}{K} \right)$	-0.061	↗	0	↗	0.063	↗	1.105	↗	1.109
$VC2 \left(10^{-2} \frac{V}{K} \right)$	-0.068	↗	0	↗	0.072	↗	1.703	↗	1.711
$T_s \left(10^{-4} \frac{V}{K} \right)$	-0.092	↗	0	↗	0.094	↗	1.657	↗	1.663
Pt ($10^{-2}V$)	-1.731	↘	-1.770	↘	-1.807	↘	-2.0370	↗	-2.0365

In the degenerate Cd- X(x) – alloy, for $N = 2 \times N_{CDP}(r_{Cd}) = 8.2813234 \times 10^{18} \text{ cm}^{-3}$, one gets:

T(K)	↗	120.32	122.93382		125.57		167.2837		167.45
ξ_p	↘	1.880	1.8138		1.750		1		0.998
$S \left(10^{-4} \frac{V}{K} \right)$	-1.562	↘	-1.563	↗	-1.562	↗	-1.322	↗	-1.320
ZT	0.999	↗	1	↘	0.999	↘	0.715	↘	0.713
$(ZT)_{Mott}$	0.931	↗	1		1.074		3.290		3.305
$VC1 \left(10^{-4} \frac{V}{K} \right)$	-0.061	↗	0	↗	0.063	↗	1.105	↗	1.109
$VC2 \left(10^{-2} \frac{V}{K} \right)$	-0.073	↗	0	↗	0.079	↗	1.848	↗	1.857
$T_s \left(10^{-4} \frac{V}{K} \right)$	-0.092	↗	0	↗	0.094	↗	1.657	↗	1.663
Pt ($10^{-2}V$)	-1.879	↘	-1.921	↘	-1.961	↘	-2.2110	↗	-2.2104

For x=1,

In the degenerate Ga- X(x) – alloy, for $N = 2 \times N_{CDP}(r_{Ga}) = 1.4673047 \times 10^{18} \text{ cm}^{-3}$, one gets:

T(K)	↗	50.606	51.70793		52.82		70.3622		70.434
ξ_p	↘	1.880	1.8138		1.750		1		0.998
$S \left(10^{-4} \frac{V}{K} \right)$	-1.562	↘	-1.563	↗	-1.562	↗	-1.322	↗	-1.320
ZT	0.999	↗	1	↘	0.998	↘	0.715	↘	0.713
$(ZT)_{Mott}$	0.931	↗	1		1.074		3.290		3.306
$VC1 \left(10^{-4} \frac{V}{K} \right)$	-0.061	↗	0	↗	0.063	↗	1.105	↗	1.109
$VC2 \left(10^{-2} \frac{V}{K} \right)$	-0.031	↗	0	↗	0.033	↗	0.777	↗	0.781
$T_s \left(10^{-4} \frac{V}{K} \right)$	-0.092	↗	0	↗	0.094	↗	1.657	↗	1.663
Pt ($10^{-2}V$)	-0.790	↘	-0.808	↘	-0.825	↘	-0.9299	↗	-0.9297

In the degenerate Mg- X(x) – alloy, for $N = 2 \times N_{CDP}(r_{Mg}) = 1.7333732 \times 10^{18} \text{ cm}^{-3}$, one gets:

T(K)	↗	56.552	57.783653		59.026		78.629815		78.71
ξ_p	↘	1.880	1.8138		1.750		1		0.998
$S \left(10^{-4} \frac{V}{K} \right)$	-1.562	↘	-1.563	↗	-1.562	↗	-1.322	↗	-1.320
ZT	0.999	↗	1	↘	0.999	↘	0.715	↘	0.713
$(ZT)_{Mott}$	0.931	↗	1		1.074		3.290		3.306

$VC1 \left(10^{-4} \frac{V}{K}\right)$	-0.061 ↗	0 ↗	0.063 ↗	1.105 ↗	1.109
$VC2 \left(10^{-2} \frac{V}{K}\right)$	-0.035 ↗	0 ↗	0.037 ↗	0.869 ↗	0.873
$T_s \left(10^{-4} \frac{V}{K}\right)$	-0.092 ↗	0 ↗	0.094 ↗	1.657 ↗	1.663
$Pt (10^{-2}V)$	-0.883 ↘	-0.903 ↘	-0.922 ↘	-1.0392 ↗	-1.0390

In the degenerate In- $X(x)$ – alloy, for $N = 2 \times N_{CDP}(r_{In}) = 1.9225022 \times 10^{18} \text{ cm}^{-3}$, one gets:

$T(K)$ ↗	60.594	61.913901	63.24	84.2501	84.335
ξ_p ↘	1.880	1.8138	1.750	1	0.998
$S \left(10^{-4} \frac{V}{K}\right)$	-1.562 ↘	-1.563 ↗	-1.562 ↗	-1.322 ↗	-1.320
ZT	0.999 ↗	1 ↘	0.999 ↘	0.715 ↘	0.713
$(ZT)_{Mott}$ ↗	0.931	1	1.074	3.290	3.305
$VC1 \left(10^{-4} \frac{V}{K}\right)$	-0.061 ↗	0 ↗	0.063 ↗	1.105 ↗	1.109
$VC2 \left(10^{-2} \frac{V}{K}\right)$	-0.037 ↗	0 ↗	0.039 ↗	0.931 ↗	0.935
$T_s \left(10^{-4} \frac{V}{K}\right)$	-0.092 ↗	0 ↗	0.094 ↗	1.657 ↗	1.663
$Pt (10^{-2}V)$	-0.946 ↘	-0.9677 ↘	-0.988 ↘	-1.1135 ↗	-1.1132

In the degenerate Cd- $X(x)$ – alloy, for $N = 2 \times N_{CDP}(r_{In}) = 2.1739166 \times 10^{18} \text{ cm}^{-3}$, one gets:

$T(K)$ ↗	65.771	67.200452	68.64	91.44384	91.537
ξ_p ↘	1.880	1.8138	1.750	1	0.998
$S \left(10^{-4} \frac{V}{K}\right)$	-1.562 ↘	-1.563 ↗	-1.562 ↗	-1.322 ↗	-1.320
ZT	0.999 ↗	1 ↘	0.999 ↘	0.715 ↘	0.713
$(ZT)_{Mott}$ ↗	0.931	1	1.074	3.290	3.306
$VC1 \left(10^{-4} \frac{V}{K}\right)$	-0.061 ↗	0 ↗	0.063 ↗	1.105 ↗	1.109
$VC2 \left(10^{-2} \frac{V}{K}\right)$	-0.040 ↗	0 ↗	0.043 ↗	1.010 ↗	1.015
$T_s \left(10^{-4} \frac{V}{K}\right)$	-0.092 ↗	0 ↗	0.094 ↗	1.657 ↗	1.663
$Pt (10^{-2}V)$	-1.027 ↘	-1.0503 ↘	-1.072 ↘	-1.2086 ↗	-1.2083

Table 6n: Here, for a given T and with decreasing N , the reduced Fermi-energy ξ_n decreases, and other thermoelectric coefficients are in variations, as indicated by the arrows as: (increase: ↗, decrease: ↘). One notes here that with increasing T : (i) for $\xi_n \simeq 1.8138$, while the numerical results of S present a same minimum $(S)_{min.} \left(\simeq -1.563 \times 10^{-4} \frac{V}{K}\right)$, those of ZT show a same maximum $(ZT)_{max.} = 1$, (ii) for $\xi_n = 1$, those of S , ZT , $(ZT)_{Mott}$, $VC1$, and T_s present the same results: $-1.322 \times 10^{-4} \frac{V}{K}$, 0.715 , 3.290 , $-1.105 \times 10^{-4} \frac{V}{K}$, and $1.657 \times 10^{-4} \frac{V}{K}$, respectively, and (iii) for $\xi_n \simeq 1.8138$, $(ZT)_{Mott} = 1$.

For $x=0$,

In the degenerate P- $X(x)$ – alloy, for $T= 44.769183 \text{ K}$, one gets:

$N(10^{17} \text{ cm}^{-3})$ ↘	3.4274	3.3719916	3.319	2.74813904	2.7466
ξ_n ↘	1.880	1.8138	1.750	1	0.998
$S \left(10^{-4} \frac{V}{K}\right)$	-1.562 ↘	-1.563 ↗	-1.562 ↗	-1.322 ↗	-1.320
ZT	0.999 ↗	1 ↘	0.998 ↘	0.715 ↘	0.713
$(ZT)_{Mott}$ ↗	0.931	1	1.074	3.290	3.305
$VC1 \left(10^{-4} \frac{V}{K}\right)$	-0.061 ↗	0 ↗	0.063 ↗	1.105 ↗	1.109

$VC2 \left(10^{-4} \frac{V}{K}\right)$	-2.746	↗	0	↗	2.817	↗	49.467	↗	49.641
$T_s \left(10^{-4} \frac{V}{K}\right)$	-0.092	↗	0	↗	0.094	↗	1.657	↗	1.663
$Pt (10^{-3}V)$	-6.993	↘	-6.997	↗	-6.993	↗	-5.917	↗	-5.910

In the degenerate As- X(x) – alloy, for T= **46.979655 K**, one gets:

$N(10^{17} cm^{-3})$	↘ 3.6843	3.6247868		3.568		2.9541646		2.9525
ξ_n	↘ 1.880	1.8138		1.750		1		0.998
$S \left(10^{-4} \frac{V}{K}\right)$	-1.562	↘ -1.563	↗	-1.562	↗	-1.322	↗	-1.320
ZT	0.999	↗ 1	↘	0.998	↘	0.715	↘	0.713
$(ZT)_{Mott}$	↗ 0.931	1		1.074		3.290		3.305
$VC1 \left(10^{-4} \frac{V}{K}\right)$	-0.061	↗ 0	↗	0.063	↗	1.105	↗	1.109
$VC2 \left(10^{-4} \frac{V}{K}\right)$	-2.879	↗ 0	↗	2.947	↗	51.910	↗	52.093
$T_s \left(10^{-4} \frac{V}{K}\right)$	-0.092	↗ 0	↗	0.094	↗	1.657	↗	1.663
$Pt (10^{-3}V)$	-7.338	↘ -7.343	↗	-7.338	↗	-6.209	↗	-6.202

In the degenerate Sb- X(x) – alloy, for T= **70.128324 K**, one gets:

$N(10^{17} cm^{-3})$	↘ 6.72	6.6108594		6.507		5.38778352		5.3846
ξ_n	↘ 1.880	1.8138		1.750		1		0.998
$S \left(10^{-4} \frac{V}{K}\right)$	-1.562	↘ -1.563	↗	-1.562	↗	-1.322	↗	-1.320
ZT	0.999	↗ 1	↘	0.999	↘	0.715	↘	0.713
$(ZT)_{Mott}$	↗ 0.931	1		1.074		3.290		3.306
$VC1 \left(10^{-4} \frac{V}{K}\right)$	-0.062	↗ 0	↗	0.063	↗	1.105	↗	1.109
$VC2 \left(10^{-4} \frac{V}{K}\right)$	-4.321	↗ 0	↗	4.411	↗	77.488	↗	77.774
$T_s \left(10^{-4} \frac{V}{K}\right)$	-0.092	↗ 0	↗	0.094	↗	1.657	↗	1.663
$Pt (10^{-3}V)$	-10.954	↘ -10.961	↗	-10.954	↗	-9.269	↗	-9.257

In the degenerate Sn- X(x) – alloy, for T=**79.154538**, one gets:

$N(10^{17} cm^{-3})$	↘ 8.058	7.9274126		7.803		6.4607611		6.457
ξ_n	↘ 1.880	1.8138		1.750		1		0.998
$S \left(10^{-4} \frac{V}{K}\right)$	-1.562	↘ -1.563	↗	-1.562	↗	-1.322	↗	-1.320
ZT	0.999	↗ 1	↘	0.999	↘	0.715	↘	0.713
$(ZT)_{Mott}$	↗ 0.931	1		1.074		3.290		3.305
$VC1 \left(10^{-4} \frac{V}{K}\right)$	-0.061	↗ 0	↗	0.063	↗	1.105	↗	1.109
$VC2 \left(10^{-4} \frac{V}{K}\right)$	-4.866	↗ 0	↗	4.974	↗	87.461	↗	87.780
$T_s \left(10^{-4} \frac{V}{K}\right)$	-0.092	↗ 0	↗	0.094	↗	1.657	↗	1.663
$Pt (10^{-3}V)$	-12.364	↘ -12.372	↗	-12.364	↗	-10.462	↗	-10.449

For x=0.5,

In the degenerate P- X(x) – alloy, for T=**20.9285725 K**, one gets:

$N(10^{16} cm^{-3})$	↘ 6.153	6.0537854		5.959		4.9337739		4.931
ξ_n	↘ 1.880	1.8138		1.750		1		0.998
$S \left(10^{-4} \frac{V}{K}\right)$	-1.562	↘ -1.563	↗	-1.562	↗	-1.322	↗	-1.320
ZT	0.999	↗ 1	↘	0.999	↘	0.715	↘	0.713
$(ZT)_{Mott}$	↗ 0.931	1		1.074		3.290		3.305
$VC1 \left(10^{-4} \frac{V}{K}\right)$	-0.061	↗ 0	↗	0.063	↗	1.105	↗	1.109
$VC2 \left(10^{-4} \frac{V}{K}\right)$	-1.280	↗ 0	↗	1.312	↗	23.125	↗	23.206
$T_s \left(10^{-4} \frac{V}{K}\right)$	-0.092	↗ 0	↗	0.094	↗	1.657	↗	1.663

Pt (10^{-3} V) -3.269 ↘ -3.271 ↗ -3.269 ↗ -2.7661 ↗ -2.7628

In the degenerate As- X(x) – alloy, for T= **21.961918 K**, one gets:

$N(10^{16}\text{cm}^{-3})$	↘	6.6143		6.5076322		6.4055		5.30365443		5.3006
ξ_n	↘	1.880		1.8138		1.750		1		0.998
$S\left(10^{-4}\frac{\text{V}}{\text{K}}\right)$		-1.562	↘	-1.563	↗	-1.562	↗	-1.322	↗	-1.320
ZT		0.999	↗	1	↘	0.999	↘	0.715	↘	0.713
$(ZT)_{\text{Mott}}$	↗	0.931		1		1.074		3.290		3.305
$VC1\left(10^{-4}\frac{\text{V}}{\text{K}}\right)$		-0.061	↗	0	↗	0.063	↗	1.105	↗	1.109
$VC2\left(10^{-4}\frac{\text{V}}{\text{K}}\right)$		-1.344	↗	0	↗	1.380	↗	24.267	↗	24.354
$T_s\left(10^{-4}\frac{\text{V}}{\text{K}}\right)$		-0.092	↗	0	↗	0.094	↗	1.657	↗	1.663
Pt (10^{-3} V)		-3.430	↘	-3.433	↗	-3.430	↗	-2.9027	↗	-2.8991

In the degenerate Sb- X(x) – alloy, for T=**32.783393 K**, one gets:

$N(10^{17}\text{cm}^{-3})$	↘	1.20636		1.1868572		1.16825		0.9672766		0.96671
ξ_n	↘	1.880		1.8138		1.750		1		0.998
$S\left(10^{-4}\frac{\text{V}}{\text{K}}\right)$		-1.562	↘	-1.563	↗	-1.562	↗	-1.322	↗	-1.320
ZT		0.999	↗	1	↘	0.999	↘	0.715	↘	0.713
$(ZT)_{\text{Mott}}$	↗	0.931		1		1.074		3.290		3.305
$VC1\left(10^{-4}\frac{\text{V}}{\text{K}}\right)$		-0.061	↗	0	↗	0.063	↗	1.105	↗	1.109
$VC2\left(10^{-4}\frac{\text{V}}{\text{K}}\right)$		-2.011	↗	0	↗	2.058	↗	36.224	↗	36.357
$T_s\left(10^{-4}\frac{\text{V}}{\text{K}}\right)$		-0.092	↗	0	↗	0.094	↗	1.657	↗	1.663
Pt (10^{-3} V)		-5.121	↘	-5.124	↗	-5.121	↗	-4.3330	↗	-4.3275

In the degenerate Sn- X(x) – alloy, for T=**37.002943 K** one gets:

$N(10^{17}\text{cm}^{-3})$	↘	1.4466		1.4232199		1.4009		1.15990983		1.15923
ξ_n	↘	1.880		1.8138		1.750		1		0.998
$S\left(10^{-4}\frac{\text{V}}{\text{K}}\right)$		-1.562	↘	-1.563	↗	-1.562	↗	-1.322	↗	-1.320
ZT		0.999	↗	1	↘	0.999	↘	0.715	↘	0.713
$(ZT)_{\text{Mott}}$	↗	0.931		1		1.074		3.290		3.305
$VC1\left(10^{-4}\frac{\text{V}}{\text{K}}\right)$		-0.061	↗	0	↗	0.063	↗	1.105	↗	1.109
$VC2\left(10^{-4}\frac{\text{V}}{\text{K}}\right)$		-2.269	↗	0	↗	2.323	↗	40.886	↗	41.036
$T_s\left(10^{-4}\frac{\text{V}}{\text{K}}\right)$		-0.092	↗	0	↗	0.094	↗	1.657	↗	1.663
Pt (10^{-3} V)		-5.780	↘	-5.783	↗	-5.780	↗	-4.8907	↗	-4.8845

For x=1,

In the degenerate P- X(x) – alloy, for T=**8.100909 K**, one gets:

$N(10^{15}\text{cm}^{-3})$	↘	5.7349		5.6422212		5.5537		4.5983533		4.5957
ξ_n	↘	1.880		1.8138		1.750		1		0.998
$S\left(10^{-4}\frac{\text{V}}{\text{K}}\right)$		-1.562	↘	-1.563	↗	-1.562	↗	-1.322	↗	-1.320
ZT		0.999	↗	1	↘	0.999	↘	0.715	↘	0.713
$(ZT)_{\text{Mott}}$	↗	0.931		1		1.074		3.290		3.305
$VC1\left(10^{-4}\frac{\text{V}}{\text{K}}\right)$		-0.061	↗	0	↗	0.063	↗	1.105	↗	1.109
$VC2\left(10^{-4}\frac{\text{V}}{\text{K}}\right)$		-0.497	↗	0	↗	0.509	↗	8.951	↗	8.983
$T_s\left(10^{-4}\frac{\text{V}}{\text{K}}\right)$		-0.092	↗	0	↗	0.094	↗	1.657	↗	1.663
Pt (10^{-3} V)		-1.265	↘	-1.266	↗	-1.265	↗	-1.0707	↗	-1.0693

In the degenerate As- X(x) – alloy, for T= **8.50088993 K**, one gets:

$N(10^{15}\text{cm}^{-3})$	↘	6.1648		6.0652134		5.970		4.9430876		4.9402
ξ_n	↘	1.880		1.8138		1.750		1		0.998

$S \left(10^{-4} \frac{V}{K} \right)$	-1.562	↘	-1.563	↗	-1.562	↗	-1.322	↗	-1.320
ZT	0.999	↗	1	↘	0.999	↘	0.715	↘	0.713
$(ZT)_{Mott}$	0.931	↗	1		1.074		3.290		3.305
$VC1 \left(10^{-4} \frac{V}{K} \right)$	-0.061	↗	0	↗	0.063	↗	1.105	↗	1.109
$VC2 \left(10^{-4} \frac{V}{K} \right)$	-0.521	↗	0	↗	0.534	↗	9.393	↗	9.427
$T_s \left(10^{-4} \frac{V}{K} \right)$	-0.092	↗	0	↗	0.094	↗	1.657	↗	1.663
Pt ($10^{-3}V$)	-1.328	↘	-1.329	↗	-1.328	↗	-1.1236	↗	-1.1221

In the degenerate Sb- X(x) – alloy, for T=**12.689603 K**, one gets:

$N(10^{16}cm^{-3})$	↘ 1.1243	1.1061692	1.0888	0.90151667	0.901
ξ_p	↘ 1.880	1.8138	1.750	1	0.998
$S \left(10^{-4} \frac{V}{K} \right)$	-1.562	↘ -1.563	↗ -1.562	↗ -1.322	↗ -1.320
ZT	0.999	↗ 1	↘ 0.999	↘ 0.715	↘ 0.713
$(ZT)_{Mott}$	0.931	1	1.074	3.290	3.305
$VC1 \left(10^{-4} \frac{V}{K} \right)$	-0.061	↗ 0	↗ 0.063	↗ 1.105	↗ 1.109
$VC2 \left(10^{-4} \frac{V}{K} \right)$	-0.776	↗ 0	↗ 0.798	↗ 14.021	↗ 14.072
$T_s \left(10^{-4} \frac{V}{K} \right)$	-0.092	↗ 0	↗ 0.094	↗ 1.657	↗ 1.663
Pt ($10^{-3}V$)	-1.982	↘ -1.983	↗ -1.982	↗ -1.6772	↗ -1.6751

In the degenerate Sn- X(x) – alloy, for T=**14.3228814 K**, one gets:

$N(10^{16}cm^{-3})$	↘ 1.3482	1.3264628	1.3057	1.0810538	1.08042
ξ_p	↘ 1.880	1.8138	1.750	1	0.998
$S \left(10^{-4} \frac{V}{K} \right)$	-1.562	↘ -1.563	↗ -1.562	↗ -1.322	↗ -1.320
ZT	0.999	↗ 1	↘ 0.999	↘ 0.715	↘ 0.713
$(ZT)_{Mott}$	0.931	1	1.074	3.290	3.305
$VC1 \left(10^{-4} \frac{V}{K} \right)$	-0.061	↗ 0	↗ 0.063	↗ 1.105	↗ 1.109
$VC2 \left(10^{-4} \frac{V}{K} \right)$	-0.876	↗ 0	↗ 0.897	↗ 15.826	↗ 15.884
$T_s \left(10^{-4} \frac{V}{K} \right)$	-0.092	↗ 0	↗ 0.094	↗ 1.657	↗ 1.663
Pt ($10^{-3}V$)	-2.237	↘ -2.239	↗ -2.237	↗ -1.8930	↗ -1.8906

Table 6p: Here, for a given T and with decreasing N, the reduced Fermi-energy ξ_p decreases, and other thermoelectric coefficients are in variations, as indicated by the arrows as: (increase: ↗, decrease: ↘). One notes here that with increasing T: (i) for $\xi_p \simeq 1.8138$, while the numerical results of S present a same minimum $(S)_{min.} \left(\simeq -1.563 \times 10^{-4} \frac{V}{K} \right)$, those of ZT show a same maximum $(ZT)_{max} = 1$, (ii) for $\xi_p = 1$, those of S, ZT, $(ZT)_{Mott}$, VC1, and T_s present the same results: $-1.322 \times 10^{-4} \frac{V}{K}$, 0.715, 3.290, $-1.105 \times 10^{-4} \frac{V}{K}$, and $1.657 \times 10^{-4} \frac{V}{K}$, respectively, and (iii) for $\xi_p \simeq 1.8138$, $(ZT)_{Mott} = 1$.

For x=0,

In the degenerate Ga- X(x) – alloy, for T=**172.18917 K**, one gets:

$N(10^{19}cm^{-3})$	↘ 1.950	1.9185205	1.8885	1.56357483	1.5627
ξ_p	↘ 1.880	1.8138	1.750	1	0.998
$S \left(10^{-4} \frac{V}{K} \right)$	-1.562	↘ -1.563	↗ -1.562	↗ -1.322	↗ -1.320
ZT	0.999	↗ 1	↘ 0.999	↘ 0.715	↘ 0.713

$(ZT)_{Mott}$	↗ 0.931	1	1.074	3.290	3.305
$VC1\left(10^{-4}\frac{V}{K}\right)$	↗ -0.061	0	↗ 0.063	↗ 1.105	↗ 1.109
$VC2(10^{-2}V)$	↗ -0.105	0	↗ 0.108	↗ 1.902	↗ 1.909
$T_s\left(10^{-4}\frac{V}{K}\right)$	↗ -0.092	0	↗ 0.094	↗ 1.657	↗ 1.663
$Pt(10^{-2}V)$	↘ -2.690	↘ -2.691	↗ -2.690	↗ -2.2758	↘ -2.2731

In the degenerate Mg- $X(x)$ – alloy, for $T=192.42153$ K, one gets:

$N(10^{19}cm^{-3})$	↘ 2.3036	2.2664086	2.2308	1.8471001	1.84601
ξ_p	↘ 1.880	1.8138	1.750	1	0.998
$S\left(10^{-4}\frac{V}{K}\right)$	↘ -1.562	↘ -1.563	↗ -1.562	↗ -1.322	↘ -1.320
ZT	↗ 0.999	↗ 1	↘ 0.999	↘ 0.715	↘ 0.713
$(ZT)_{Mott}$	↗ 0.931	1	1.074	3.290	3.306
$VC1\left(10^{-4}\frac{V}{K}\right)$	↗ -0.061	0	↗ 0.063	↗ 1.105	↗ 1.109
$VC2(10^{-2}V)$	↗ -0.118	0	↗ 0.121	↗ 2.126	↗ 2.134
$T_s\left(10^{-4}\frac{V}{K}\right)$	↗ -0.092	0	↗ 0.094	↗ 1.657	↗ 1.663
$Pt(10^{-2}V)$	↘ -3.006	↘ -3.007	↗ -3.006	↗ -2.5432	↘ -2.5400

In the degenerate In- $X(x)$ – alloy, for $T=206.175403$ K, one gets:

$N(10^{19}cm^{-3})$	↘ 2.555	2.5136974	2.2308	2.04863793	2.04743
ξ_p	↘ 1.880	1.8138	1.750	1	0.998
$S\left(10^{-4}\frac{V}{K}\right)$	↘ -1.562	↘ -1.563	↗ -1.562	↗ -1.322	↘ -1.320
ZT	↗ 0.999	↗ 1	↘ 0.999	↘ 0.715	↘ 0.713
$(ZT)_{Mott}$	↗ 0.931	1	1.074	3.290	3.306
$VC1\left(10^{-4}\frac{V}{K}\right)$	↗ -0.061	0	↗ 0.063	↗ 1.105	↗ 1.109
$VC2(10^{-2}V)$	↗ -0.126	0	↗ 0.121	↗ 2.278	↗ 2.286
$T_s\left(10^{-4}\frac{V}{K}\right)$	↗ -0.092	0	↗ 0.094	↗ 1.657	↗ 1.663
$Pt(10^{-2}V)$	↘ -3.220	↘ -3.222	↗ -3.006	↗ -2.7250	↘ -2.7215

In the degenerate Cd- $X(x)$ – alloy, for $T=223.779792$ K, one gets:

$N(10^{19}cm^{-3})$	↘ 2.889	2.842425	2.79776	2.3165476	2.3152
ξ_p	↘ 1.880	1.8138	1.750	1	0.998
$S\left(10^{-4}\frac{V}{K}\right)$	↘ -1.562	↘ -1.563	↗ -1.562	↗ -1.322	↘ -1.320
ZT	↗ 0.999	↗ 1	↘ 0.999	↘ 0.715	↘ 0.713
$(ZT)_{Mott}$	↗ 0.931	1	1.074	3.290	3.305
$VC1\left(10^{-4}\frac{V}{K}\right)$	↗ -0.061	0	↗ 0.063	↗ 1.105	↗ 1.109
$VC2(10^{-2}V)$	↗ -0.137	0	↗ 0.141	↗ 2.473	↗ 2.482
$T_s\left(10^{-4}\frac{V}{K}\right)$	↗ -0.092	0	↗ 0.094	↗ 1.657	↗ 1.663
$Pt(10^{-2}V)$	↘ -3.495	↘ -3.498	↗ -3.495	↗ -2.9577	↘ -2.9540

For $x=0.5$,

In the degenerate Ga- $X(x)$ – alloy, for $T=94.59242$ K, one gets:

$N(10^{19}cm^{-3})$	↘ 5.6814	5.5895544	5.502	4.5554303	4.5528
ξ_p	↘ 1.880	1.8138	1.750	1	0.998
$S\left(10^{-4}\frac{V}{K}\right)$	↘ -1.562	↘ -1.563	↗ -1.562	↗ -1.322	↘ -1.320
ZT	↗ 0.999	↗ 1	↘ 0.999	↘ 0.715	↘ 0.713
$(ZT)_{Mott}$	↗ 0.931	1	1.074	3.290	3.305
$VC1\left(10^{-4}\frac{V}{K}\right)$	↗ -0.061	0	↗ 0.063	↗ 1.105	↗ 1.109
$VC2(10^{-2}V)$	↗ -0.058	0	↗ 0.059	↗ 1.045	↗ 1.049
$T_s\left(10^{-4}\frac{V}{K}\right)$	↗ -0.092	0	↗ 0.094	↗ 1.657	↗ 1.663
$Pt(10^{-2}V)$	↘ -1.477	↘ -1.478	↗ -1.477	↗ -1.2502	↘ -1.2487

In the degenerate Mg- X(x) – alloy, for T=105.707108 K, one gets:

$N(10^{18}\text{cm}^{-3})$	↘	6.7115		6.6031166		6.4994		5.3814733		5.3783
ξ_p	↘	1.880		1.8138		1.750		1		0.998
$S\left(10^{-4}\frac{V}{K}\right)$		-1.562	↘	-1.563	↗	-1.562	↗	-1.322	↗	-1.320
ZT		0.999	↗	1	↘	0.999	↘	0.715	↘	0.713
$(ZT)_{\text{Mott}}$		0.931		1		1.074		3.290		3.305
$VC1\left(10^{-4}\frac{V}{K}\right)$		-0.061	↗	0	↗	0.063	↗	1.105	↗	1.109
$VC2(10^{-2}V)$		-0.065	↗	0	↗	0.066	↗	1.168	↗	1.172
$T_s\left(10^{-4}\frac{V}{K}\right)$		-0.092	↗	0	↗	0.094	↗	1.657	↗	1.663
$Pt(10^{-2}V)$		-1.651	↘	-1.652	↗	-1.651	↗	-1.3971	↗	-1.3953

In the degenerate In- X(x) – alloy, for T=113.262816 K, one gets:

$N(10^{18}\text{cm}^{-3})$	↘	7.444		7.323585		7.209		5.9686477		5.9652
ξ_p	↘	1.880		1.8138		1.750		1		0.998
$S\left(10^{-4}\frac{V}{K}\right)$		-1.562	↘	-1.563	↗	-1.562	↗	-1.322	↗	-1.320
ZT		0.999	↗	1	↘	0.999	↘	0.715	↘	0.713
$(ZT)_{\text{Mott}}$		0.931		1		1.074		3.290		3.305
$VC1\left(10^{-4}\frac{V}{K}\right)$		-0.061	↗	0	↗	0.063	↗	1.105	↗	1.109
$VC2(10^{-2}V)$		-0.069	↗	0	↗	0.071	↗	1.251	↗	1.256
$T_s\left(10^{-4}\frac{V}{K}\right)$		-0.092	↗	0	↗	0.094	↗	1.657	↗	1.663
$Pt(10^{-2}V)$		-1.769	↘	-1.770	↗	-1.769	↗	-1.4970	↗	-1.4951

In the degenerate Cd- X(x) – alloy, for T=122.93382 K, one gets:

$N(10^{18}\text{cm}^{-3})$	↘	8.417		8.2813234		8.1512		6.7491949		6.7452
ξ_p	↘	1.880		1.8138		1.750		1		0.998
$S\left(10^{-4}\frac{V}{K}\right)$		-1.562	↘	-1.563	↗	-1.562	↗	-1.322	↗	-1.320
ZT		0.999	↗	1	↘	0.999	↘	0.715	↘	0.713
$(ZT)_{\text{Mott}}$		0.931		1		1.074		3.290		3.306
$VC1\left(10^{-4}\frac{V}{K}\right)$		-0.061	↗	0	↗	0.063	↗	1.105	↗	1.109
$VC2(10^{-2}V)$		-0.075	↗	0	↗	0.077	↗	1.358	↗	1.363
$T_s\left(10^{-4}\frac{V}{K}\right)$		-0.092	↗	0	↗	0.094	↗	1.657	↗	1.663
$Pt(10^{-2}V)$		-1.920	↘	-1.921	↗	-1.920	↗	-1.6248	↗	-1.6227

For x=1,

In the degenerate Ga- X(x) – alloy, for T=51.70793 K, one gets:

$N(10^{18}\text{cm}^{-3})$	↘	1.4914		1.4673047		1.4443		1.1958385		1.19513
ξ_p	↘	1.880		1.8138		1.750		1		0.998
$S\left(10^{-4}\frac{V}{K}\right)$		-1.562	↘	-1.563	↗	-1.562	↗	-1.322	↗	-1.320
ZT		0.999	↗	1	↘	0.999	↘	0.715	↘	0.713
$(ZT)_{\text{Mott}}$		0.931		1		1.074		3.290		3.306
$VC1\left(10^{-4}\frac{V}{K}\right)$		-0.061	↗	0	↗	0.063	↗	1.105	↗	1.109
$VC2(10^{-2}V)$		-0.032	↗	0	↗	0.032	↗	0.571	↗	0.573
$T_s\left(10^{-4}\frac{V}{K}\right)$		-0.092	↗	0	↗	0.094	↗	1.657	↗	1.663
$Pt(10^{-2}V)$		-0.8077	↘	-0.8082	↗	-0.8077	↗	-0.6834	↗	-0.6825

In the degenerate Mg- X(x) – alloy, for T=57.783653 K, one gets:

$N(10^{18}\text{cm}^{-3})$	↘	1.7618		1.7333732		1.70615		1.41268163		1.41185
ξ_p	↘	1.880		1.8138		1.750		1		0.998
$S\left(10^{-4}\frac{V}{K}\right)$		-1.562	↘	-1.563	↗	-1.562	↗	-1.322	↗	-1.320
ZT		0.999	↗	1	↘	0.999	↘	0.715	↘	0.713

$(ZT)_{Mott}$	↗ 0.931	1	↗ 1.074	3.290	↗ 3.306
$VC1\left(10^{-4}\frac{V}{K}\right)$	↗ -0.061	0	↗ 0.063	1.105	↗ 1.109
$VC2(10^{-2}V)$	↗ -0.035	0	↗ 0.036	0.638	↗ 0.641
$T_s\left(10^{-4}\frac{V}{K}\right)$	↗ -0.092	0	↗ 0.094	1.657	↗ 1.663
$Pt(10^{-2}V)$	↘ -0.9026	↘ -0.9031	↘ -0.9026	↘ -0.7637	↘ -0.7627

In the degenerate In- X(x) – alloy, for T=**61.913901** K, one gets:

$N(10^{18}cm^{-3})$	↘ 1.9540	1.9225022	↘ 1.8923	1.56681982	↘ 1.5659
ξ_p	↘ 1.880	1.8138	↘ 1.750	1	↘ 0.998
$S\left(10^{-4}\frac{V}{K}\right)$	↘ -1.562	↘ -1.563	↘ -1.562	↘ -1.322	↘ -1.320
ZT	↗ 0.999	1	↘ 0.999	0.715	↘ 0.713
$(ZT)_{Mott}$	↗ 0.931	1	↗ 1.074	3.290	↗ 3.305
$VC1\left(10^{-4}\frac{V}{K}\right)$	↗ -0.061	0	↗ 0.063	1.105	↗ 1.109
$VC2(10^{-2}V)$	↗ -0.038	0	↗ 0.039	0.684	↗ 0.687
$T_s\left(10^{-4}\frac{V}{K}\right)$	↗ -0.092	0	↗ 0.094	1.657	↗ 1.663
$Pt(10^{-2}V)$	↘ -0.9671	↘ -0.9677	↘ -0.9671	↘ -0.8183	↘ -0.8173

In the degenerate Cd- X(x) – alloy, for T=**67.200452** K, one gets:

$N(10^{18}cm^{-3})$	↘ 2.2096	2.1739166	↘ 2.1398	1.77172003	↘ 1.7707
ξ_p	↘ 1.880	1.8138	↘ 1.750	1	↘ 0.998
$S\left(10^{-4}\frac{V}{K}\right)$	↘ -1.562	↘ -1.563	↘ -1.562	↘ -1.322	↘ -1.320
ZT	↗ 0.999	1	↘ 0.999	0.715	↘ 0.713
$(ZT)_{Mott}$	↗ 0.931	1	↗ 1.074	3.290	↗ 3.305
$VC1\left(10^{-4}\frac{V}{K}\right)$	↗ -0.061	0	↗ 0.063	1.105	↗ 1.109
$VC2(10^{-2}V)$	↗ -0.041	0	↗ 0.042	0.742	↗ 0.745
$T_s\left(10^{-4}\frac{V}{K}\right)$	↗ -0.092	0	↗ 0.094	1.657	↗ 1.663
$Pt(10^{-2}V)$	↘ -1.0497	↘ -1.0503	↘ -1.0497	↘ -0.8882	↘ -0.8871